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**UTILITY  
PATENT APPLICATION  
TRANSMITTAL**  
Form for new nonprovisional applications under 37 CFR 1.53(b)

Attorney Docket No. 199143US2SRD

First Inventor or Application Identifier Shoji OTAKA, et al.

Title VARIABLE GAIN CIRCUIT

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**APPLICATION ELEMENTS***See MPEP chapter 600 concerning utility patent application contents*

1.  Fee Transmittal Form (e.g. PTO/SB/17)  
(Submit an original and a duplicate for fee processing)

2.  Specification Total Sheets **45**

3.  Drawing(s) (35 U.S.C. 113) Total Sheets **11**  
**(Formals)**

4.  Oath or Declaration Total Pages **2**

a.  Newly executed (original)

b.  Copy from a prior application (37 C.F.R. §1.63(d))  
(for continuation / divisional w/ box 16 completed)

i.  **DELETION OF INVENTOR(S)**  
Signed statement attached deleting inventor(s) named in  
the prior application, see 37 C.F.R. §1.63(d)(2) and  
1.33(b).

5.  CD-ROM or CD-R in duplicate, large table or Computer  
Program (Appendix)

6.  Nucleotide and/or Amino Acid Sequence Submission  
*(if applicable, all necessary)*

a.  Computer Readable Form (CRF)

b. Specification or Sequence Listing on:

i.  CD-ROM or CD-R (2 copies); or

ii.  Paper

c.  Statements verifying identity of above copies

**ACCOMPANYING APPLICATION PARTS**

7.  Assignment Papers (cover sheet & document(s))

8.  Application Data Sheet. See 37 CFR 1.76

9.  37 C.F.R. §3.73(b) Statement *(when there is an assignee)*  Power of Attorney

10.  English Translation Document *(if applicable)*

11.  Information Disclosure Statement (IDS)/PTO-1449  Copies of IDS Citations (3)

12.  Preliminary Amendment

13.  White Advance Serial No. Postcard

14.  Certified Copy of Priority Document(s)  
*(if foreign priority is claimed)*

15.  Applicant claims small entity status.  
*See 37 CFR 1.27*

16.  Other: Notice of Priority, List of Related Cases, Statement of Relevancy

## 16. If a CONTINUING APPLICATION, check appropriate box, and supply the requisite information below:

Continuation  Divisional  Continuation-in-part (CIP) of prior application no.:

Prior application information: Examiner:

Group Art Unit:

For CONTINUATION OR DIVISIONAL APPS only: The entire disclosure of the prior application, from which an oath or declaration is supplied under Box 4b, is considered a part of the accompanying continuation or divisional application and is hereby incorporated by reference. The incorporation can only be relied upon when a portion has been inadvertently omitted from the submitted application parts.

## 17. Amend the specification by inserting before the first line the sentence:

This application is a  Continuation  Division  Continuation-in-part (CIP)  
of application Serial No. Filed on

This application claims priority of provisional application Serial No. Filed

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Docket No. 199143US2SRD

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

INVENTOR(S) Shoji OTAKA, et al.  
SERIAL NO: New Application  
FILING DATE: Herewith  
FOR: VARIABLE GAIN CIRCUIT

**FEE TRANSMITTAL**

ASSISTANT COMMISSIONER FOR PATENTS  
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Respectfully Submitted,

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TITLE OF THE INVENTION

VARIABLE GAIN CIRCUIT

CROSS-REFERENCE TO RELATED APPLICATIONS

This application is based upon and claims the  
5 benefit of priority from the prior Japanese Patent  
Applications No. 11-306798, filed October 28, 1999; and  
No. 2000-284708, filed September 20, 2000, the entire  
contents of which are incorporated herein by reference.

BACKGROUND OF THE INVENTION

10 The present invention relates to a variable gain  
circuit which is used for a portable radio transceiver  
or the like to linearly change the gain displayed in  
decibels (dB) in accordance with a gain control signal.

Recently, mobile communication facilities typified  
15 by portable telephones have been vigorously developed.  
These communication facilities are carried by users and  
mounted on automobiles and the like when they are used,  
and hence required to be reduced in size and weight.  
It is therefore strongly desired that the components of  
20 such a radio device be implemented in monolithic IC  
(Integrated Circuit) form suited for reductions in size  
and weight rather than being implemented in hybrid form  
having many components connected to each other as in  
the prior art.

25 There have been demands for a reduction in the  
cost of radio devices as well as a reduction in the  
size of components. The IC technology is also

effective for a reduction in the cost of radio devices.

In addition, transmission power control is indispensable to CDMA (Code Division Multiple Access) radio transceivers that have been increasingly developed in recent years. Under certain circumstances, therefore, a transmission IF (Intermediate Frequency) variable gain circuit is required to perform signal level control on 70 dB or higher. In general, to perform such high-level gain control, the gain displayed in decibels is required to be linearly adjusted in accordance with a gain control signal. This operation is required to facilitate gain control.

FIG. 16 is a circuit diagram of a conventional variable gain circuit using bipolar transistors. This variable gain circuit is comprised of a variable gain amplifier 1 and a control signal compensation circuit 2. Bipolar transistors Q1 and Q2 constitute a differential pair. An IF signal (input current  $I_{sig}$ ) is input to the common emitter terminal. An output current  $I_a$  is extracted from the collector terminal of the bipolar transistor Q1. To generate the output current  $I_a$  from an input current  $I_{sig}$ , a gain control signal  $V_{z1}$  is input between the base terminals of the bipolar transistors Q1 and Q2. Note that the arrows in FIG. 16 indicate the directions of currents.

A current  $I_{sig}-I_a$  flowing in the collector of the bipolar transistor Q2 is regarded as an unwanted

current and designed to flow in a power supply (not shown) or the like. In this case, a transfer function from  $I_{sig}$  to  $I_a$  is represented by

5

$$\frac{I_a}{I_{sig}} = \frac{1}{1 + \exp\left(\frac{V_{z1}}{V_T}\right)} \quad (1)$$

where  $V_T$  is the thermal voltage, which is about 26 mV at room temperature.

10 According to equation (1), under the condition of  $1 \ll \exp(V_{z1}/V_T)$ , the transfer function can be approximated by  $I_a/I_{sig} = 1/\exp(V_{z1}/V_T)$ . Obviously, as the gain control signal  $V_{z1}$  increases, the gain  $(I_a/I_{sig})$  exponentially decreases.

15 If the above hypothesis ( $1 \ll \exp(V_{z1}/V_T)$ ) does not hold, the relationship between the gain control signal  $V_{z1}$  and the gain  $(I_a/I_{sig})$  deviates from an exponential relationship. That is, if the hypothesis of  $1 \ll \exp(V_{z1}/V_T)$  does not hold with respect to the gain control signal  $V_{z1}$ , the relationship between the gain  $(I_a/I_{sig})$  displayed in decibels and the gain control signal  $V_{z1}$  becomes nonlinear. For this reason, 20 there is proposed a variable gain circuit whose gain  $(I_a/I_{sig})$  decreases exponentially with respect to an internal gain control signal  $V_x$  by using a gain control signal compensation circuit 2 comprised of the 25 bipolar transistors  $Q10$  and  $Q11$ , a current source  $I_o$ , a voltage source  $V_{BB}$ , and a gain control current source  $I_1 = I_o \cdot \exp(-b \cdot V_x)$  for gain correction [see Japanese

Patent Application No. 10-370290 (Jpn. Pat. Appln.

KOKAI Publication No. 2000-196386) as the specification of a previous application]. When this gain control signal compensation circuit 2 is used, the gain control

5 signal  $V_x$  and gain ( $I_a/I_{sig}$ ) are given by

$$\frac{I_a}{I_{sig}} = \exp(-b \cdot V_x) \quad (2)$$

where  $b$  is a constant, which is 2 to 4, for example.

FIG. 17A is a block diagram of a conventional variable gain circuit using bipolar transistors. FIG. 17B is a graph showing the relationship between an external gain control signal  $V_c$  supplied from the outside of the variable gain circuit and a voltage gain GAIN ( $V_{out}/V_{in}$ ) (dB). Reference symbol (dB) denotes a gain displayed in decibels; ditto for the following description. In this case, the external gain control signal  $V_c$  is equal to the internal gain control signal  $V_x$ , and  $I_{sig} = g_1 \cdot V_{in}$  and  $I_a = g_2 \cdot V_{out}$ , where  $g_1$  and  $g_2$  are the conductance, which is, for example, 0.1(A/V).

20 By using the block arrangement shown in FIG. 17A, the internal gain control signal  $V_x$  and gain ( $I_a/I_{sig}$ ) have an exponential relationship. However, this relationship holds only when bipolar transistors are used.

25 More specifically, if the variable gain circuit in FIG. 16 is formed by using field-effect transistors (FETs), the internal gain control signal  $V_x$  and gain

( $I_a/I_{sig}$ ) cease to have an exponential relationship.

This problem will be described in detail below.

Note that the following FETs indicate n-type (n-channel) MOS transistors (MOSFETs) unless otherwise specified.

FIG. 18 shows the variable gain circuit in FIG. 16 which is formed by using MOSFETs, assuming that FETs are MOSFETs. In this case, with the use of the internal gain control signal  $V_x$ ,  $I_{D1}$  is given by

$$I_{D1} = I_o \cdot \exp(-b \cdot V_x) \quad (3)$$

where  $I_o$  is the current value of a constant current source, and  $b$  is a constant. Referring to FIG. 18,  $I_{D2} = I_o - I_{D1}$  holds. When this circuit is designed so that the current densities of the transistors M1 and M2 equal to those of the transistors M10 and M11, a current gain  $G_{MOS}$  ( $= I_{out1}/I_{sig1}$ ) of a variable gain amplifier 11 is given by

$$G_{MOS} = \frac{g_{m11}}{g_{m11} + g_{m10}} = \frac{g_{m1}}{g_{m1} + g_{m2}} \quad (4)$$

where  $g_{m1}$ ,  $g_{m2}$ ,  $g_{m10}$  and  $g_{m11}$  are the transconductance of MOS transistors M1, M2, M10 and M11. Assuming that each of the transistors M10 and M11 exhibits a square characteristic which is a characteristic in a strong inversion, the relationships between currents  $I_{D10}$  and  $I_{D11}$  and gate voltages  $V_{GS10}$  and  $V_{GS11}$  are expressed as

$$I_{D10} = \beta (V_{GS10} - V_{TH})^2 \quad (5)$$

$$I_{D11} = \beta (V_{GS11} - V_{TH})^2 \quad (6)$$

where  $I_{D10}$  is the drain current of the transistor M10,  $I_{D11}$  is the drain current of the transistor M11,  $V_{GS10}$  is the gate-to-source voltage of the transistor M10,  $V_{GS11}$  is the gate-to-source voltage of the transistor M11,  $\beta$  is  $\mu \cdot C_{ox} \cdot W / (2L)$ ,  $\mu$  is the mobility of carriers,  $C_{ox}$  is the oxide film capacitance per unit area,  $W$  is the channel width,  $L$  is the channel length, and  $V_{TH}$  is the threshold voltage. From equations (4), (5), and (6),  $G_{MOS}$  is given by

10

$$G_{MOS} = \frac{2\sqrt{\beta \cdot I_{D1}}}{2(\sqrt{\beta \cdot I_{D1}} + \sqrt{\beta \cdot I_{D2}})} \quad (7)$$

$$= \sqrt{\frac{I_{D1}}{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}}} \quad (8)$$

$$= \sqrt{\frac{I_o \cdot \exp(-b \cdot V_x)}{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}}} \quad (9)$$

15

According to equation (9), if  $I_{D1} \gg I_{D2}$  or  $I_{D1} \ll I_{D2}$ , the denominator in the root in the equation (9) can be approximated by  $I_o$ . Equation (9) can therefore be rewritten as:

$$G_{MOS} = \sqrt{\exp(-b \cdot V_x)} \quad (10)$$

20

It is obvious from equations (10) and (2) that the relationship between the gain (dB) and the internal gain control signal  $V_x$  in the case where MOSFETs are used gradually approaches a straight line with a half slope as compared with the case where bipolar transistors are used.

If  $I_{D1} = I_{D2} = I_o/2$ , i.e.,  $V_{z1} = 0$ , since the

denominator in the root in equation (9) becomes  $2I_o$ ,  
the gain takes a value as low as 3 dB with respect to  
the asymptote based on the gain control signal  $V_x$  and  
the gain  $G_{MOS}$  (dB) obtained in the case where MOSFETs  
5 are used. If  $I_{D1} \ll I_{D2}$ , the current characteristic of  
each of the MOSFETs M1 and M11 deviates from the square  
characteristic and has an exponential characteristic.  
This characteristic is obtained when the transistor is  
in a weak inversion and approximated by  
10

$$I_{D1} = A \cdot \exp\{c(V_{GS} - V_{TH1})\} \quad (11)$$

where A, c, and  $V_{TH}$  are constants, and  $V_{GS}$  is the gate-  
to-source voltage of the transistor M1. At this time,  
15  $g_{m1} = c \cdot I_{D1}$ , the gain  $G_{MOS}$  can be approximated by

$$G_{MOS} = \frac{c \cdot I_{D1}}{c \cdot I_{D1} + 2\sqrt{\beta \cdot I_{D2}}} \quad (12)$$

$$\sim \frac{c \cdot I_o \cdot \exp(-b \cdot V_x)}{2\sqrt{\beta \cdot I_o}} \quad (13)$$

where  $c \cdot I_{D1} \ll 2\sqrt{(\beta \cdot I_{D2})}$  and  $I_{D2}$  is up to  $I_o$ . From  
this equation, if  $I_{D1} \ll I_{D2}$ , the same slope as that of  
the characteristic curve based on bipolar transistors  
20 is obtained.

Gain characteristics in consideration of the two  
operation regions of MOSFETs described above are shown  
in FIG. 1A. As is obvious from FIG. 1A as well, when  
MOSFETs are used, the gain (dB) does not change  
25 linearly with respect to the external gain control  
signal  $V_c$  ( $= V_x$ ). In controlling the gain of a radio  
transceiver, for the sake of easy control, it is

required that the relationship between the gain (dB) displayed in decibels and the external gain control signal  $V_c$  can be linearly approximated. According to the characteristics of a variable gain circuit using 5 MOSFETS, in particular, the relationship between the gain (dB) and the external gain control signal  $V_x$  cannot be linearly approximated in the condition that VGA's gain is high. If gain control is performed within the range in which linear approximation can be 10 performed, the gain control range narrows. Accordingly, the number of variable gain amplifiers must be increased, resulting in an increase in current consumption. Furthermore, in general, an amplifier has low-noise characteristics at high gain, and hence the 15 noise characteristics deteriorate.

#### BRIEF SUMMARY OF THE INVENTION

It is an object of the present invention to provide a variable gain circuit which uses field-effect transistors and can linearly adjust the gain displayed 20 in decibels in accordance with an externally supplied control signal.

According to a first aspect of the invention, there is provided a variable gain circuit comprising a variable gain amplifier which receives an input signal, 25 outputs an amplified signal, and includes a first field-effect transistor, a gain control signal compensation circuit which outputs a gain control

signal for controlling a gain of the variable gain amplifier and includes a second field-effect transistor, and a gain deviation correction circuit which corrects a gain deviation based on the amplified signal of the variable gain amplifier and the gain control signal of the gain control signal compensation circuit.

According to a second aspect of the invention, there is provided a variable gain circuit comprising a first variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor, a second variable gain amplifier which receives the amplified signal, outputs an amplified output signal, and includes a second field-effect transistor, a first gain control signal compensation circuit which outputs a first gain control signal for controlling a gain of the first variable gain amplifier and includes a third field-effect transistor, a second gain control signal compensation circuit which outputs a second control signal for controlling a gain of the second variable gain amplifier, and a third gain control signal compensation circuit which receives an externally supplied external gain control signal, converts the external gain control signal into an internal gain control signal, and outputs the internal gain control signal to the first and second gain control signal compensation circuits.

According to a third aspect of the invention,

there is provided a variable gain circuit comprising a first variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor, a second variable gain 5 amplifier which receives the amplified signal, outputs an amplified output signal, and includes a second field-effect transistor, a first gain control signal compensation circuit which outputs a first gain control signal for controlling a gain of the first variable 10 gain amplifier and includes a third field-effect transistor, a second gain control signal compensation circuit which receives the first gain control signal and outputs a second gain control signal for controlling a gain of the second variable gain 15 amplifier, and a third gain control signal compensation circuit which receives an externally supplied external gain control signal, converts the external gain control signal into an internal gain control signal, and outputs the internal gain control signal to the first 20 gain control signal compensation circuit.

Additional objects and advantages of the invention will be set forth in the description which follows, and in part will be obvious from the description, or may be learned by practice of the invention. The objects 25 and advantages of the invention may be realized and obtained by means of the instrumentalities and combinations particularly pointed out hereinafter.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWINGS

The accompanying drawings, which are incorporated in and constitute a part of the specification, illustrate presently preferred embodiments of the invention, and together with the general description given above and the detailed description of the preferred embodiments given below, serve to explain the principles of the invention.

FIGS. 1A to 1D are graphs showing the characteristics of a variable gain circuit and a correction method according to the present invention;

FIG. 2 is a block diagram showing a variable gain circuit according to the first embodiment of the present invention;

FIG. 3 is a block diagram showing a variable gain circuit according to the second embodiment of the present invention;

FIG. 4 is a circuit diagram showing a first gain control signal compensation circuit 102;

FIG. 5 is a circuit diagram showing a first variable gain amplifier 101;

FIG. 6 is a circuit diagram showing a second gain control signal compensation circuit 202 and fourth control signal compensation circuit 212;

FIG. 7 is a circuit diagram showing the details of the variable gain circuit in FIG. 2;

FIG. 8 is a circuit diagram showing the details of

the variable gain circuit in FIG. 3;

FIG. 9 is a circuit diagram of a voltage/current converter 400;

5 FIG. 10 shows the input/output characteristics of a third gain control signal compensation circuit 300;

FIG. 11 is a circuit diagram of the third gain control signal compensation circuit 300;

FIG. 12 is a circuit diagram of the first variable gain amplifier 101 formed by a differential circuit;

10 FIG. 13 is a circuit diagram showing the variable gain circuit in FIG. 8 formed by a differential circuit;

FIG. 14 is a circuit diagram of a variable gain circuit having a two-stage configuration;

15 FIG. 15 is a block diagram showing an example of the arrangement of the radio circuit section of a heterodyne radio transceiver;

FIG. 16 is a circuit diagram of a conventional variable gain circuit using bipolar transistors;

20 FIGS. 17A and 17B are a block diagram of the conventional variable gain circuit using bipolar transistors and a graph showing the relationship between a gain control signal  $V_C$  and a voltage gain GAIN ( $V_{out}/V_{in}$ ); and

25 FIG. 18 is a circuit diagram showing a case where the bipolar transistors of the variable gain circuit in FIG. 16 are replaced with MOSFETs.

DETAILED DESCRIPTION OF THE INVENTION

Embodiments of the present invention will be described below with reference to the views of the accompanying drawing. The solid line in FIG. 1A represents the gain (dB)-gain control signal characteristic of a circuit (FIG. 16) obtained by replacing the bipolar transistors of the variable gain circuit having the gain correction circuit, described in the prior art (FIG. 18), with FETs.

In the present invention, the FETs are assumed to be MOS field effect transistors (MOSFETs) which are most generally used. As described in the prior art, if external gain control signal  $V_c = V_{c2}$ , i.e.,  $I_{D1} = I_{D2}$  or  $V_{z1} = 0$  V (FIG. 18), the gain decreases by 3 dB from the characteristic curve (dotted line) which linearly approximates the gain (dB)-gain control signal characteristic. In addition, when  $V_c > V_{c1}$ , i.e., the MOSFETs are set in a weak inverse region, the slope of the gain-control signal characteristic (the slope of the dashed line) becomes almost twice as large as that when  $V_c < V_{c1}$ , according to equations (10) and (13).

The present invention makes the gain (dB)-gain control signal characteristic exhibit a linear characteristic within the range of  $V_c \geq 0$  by adding a gain correction function to this characteristic. This characteristic will be referred to as linear-in-dB characteristic hereinafter. The purpose of obtaining

the linear-in-dB characteristic is to implement a low-power-consumption, low-noise variable gain circuit.

To obtain the linear-in-dB characteristic, the present invention performs the following two gain 5 correcting operations. In the first operation, as shown in FIG. 1B, gain correction is performed near  $I_{D1} = I_{D2}$ .

The second operation is performed to correct the gain deviation due to the transition of the operation 10 region of each MOSFET from a strong inversion region to a weak inversion region. FIG. 1C is a graph showing this correct. Note that the second correction is not required when FETs having no inverted layers, e.g., J-FETs (Junction Field-Effect Transistors) or MESFETs 15 (Schottky junction field effect transistors), are used. By performing the corrections shown in FIGS. 1B and 1C, a linear-in-dB characteristic can be obtained even if MOSFETs are used. FIG. 1D shows this characteristic.

(First Embodiment)

20 FIG. 2 is a block diagram showing a variable gain circuit according to the first embodiment which implements the gain correction method shown in FIGS. 1A to 1D. Reference symbols  $V_{IN}$ ,  $V_{OUT}$ , and  $V_C$  respectively denote an input terminal for a desired signal to 25 be gain-controlled (signal to be controlled), an output terminal for the desired signal, and an external gain control signal input terminal. An external gain

control signal  $V_C$  supplied from the outside of the variable gain circuit is converted into an internal gain control signal  $V_X$  through a third gain control signal compensation circuit 300. In this case, as shown in FIG. 1C, an external gain control signal  $V_C$  is converted with a gain  $a+b$  up to  $V_{C1}$ , and converted to  $V_{C2}$  or higher with a gain  $a$ . The internal gain control signal  $V_X$  is input to a first gain control signal compensation circuit 102 and second gain control signal compensation circuit 202 to be converted into first and second gain control signals  $V_{Z1}$  and  $V_{Z2}$ , respectively. The first and second gain control signals  $V_{Z1}$  and  $V_{Z2}$  are respectively input to the gain control signal input terminals of first and second variable gain amplifiers 101 and 201. A desired signal  $V_{IN}$  is input to the first variable gain amplifier 101 and gain-controlled in accordance with the gain control signal  $V_{Z1}$ . The desired signal (amplified signal) gain-controlled by the first variable gain amplifier 101 is input to the second gain amplifier 201 to be gain-controlled in accordance with the gain control signal  $V_{Z2}$  and output as an output signal  $V_{OUT}$ . The input/output characteristics of the first and second gain control signal compensation circuits 102 and 202 will be described later, together with their circuit arrangements.

The second gain control signal compensation circuit 202 and second gain amplifier 201 in FIG. 2

constitute a gain deviation correction circuit for correcting a gain deviation produced near  $I_{D1} = I_{D2}$  in the manner shown in FIG. 1B.

(Second Embodiment)

5 FIG. 3 is a block diagram showing a variable gain circuit according to the second embodiment. This circuit differs from the one shown in FIG. 2 in that the second gain control signal compensation circuit 202 is replaced with a fourth control signal compensation circuit 212, and an input signal to the fourth control signal compensation circuit 212 is a gain control signal  $V_{z1}$  which is an output signal from a first gain control signal compensation circuit 102.

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15 The first gain control signal compensation circuit 102, the fourth control signal compensation circuit 212, and a second variable gain amplifier 201 in FIG. 3 constitute a gain deviation correction circuit for correcting a gain deviation produced near  $I_{D1} = I_{D2}$  in the manner shown in FIG. 1B.

20

If the gain deviation correction circuit shown in FIGS. 2 and 3 has a gain characteristic  $G_{CMP}$ :

$$G_{CMP} = \sqrt{\frac{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}}{I_o}} \quad (14)$$

25 it is obvious from equation (9) that gain correction can be performed.

In addition, even if the gain characteristic  $G_{CMP}$  given by equation (14) cannot be accurately obtained,

gain correction can be performed as long as the characteristic has an approximate means for equation (14).

The first variable gain amplifier 101 described above is designed in consideration of a single-stage arrangement. An arrangement obtained by n-stage cascade connection will be described next. Assume that n first variable gain amplifiers 101 are cascaded, and the gain control signal  $V_{z1}$  from the first gain control signal compensation circuit 102 is supplied to each gain stage. In this case, a gain  $G_{CMP}$  of the first variable gain amplifiers 101 becomes n times higher than that given by equation (9). Letting  $A'$  be a constant of proportionality, the gain  $G_{MOSn}$  is given by

$$G_{MOSn} = A' \left\{ \frac{I_o \cdot \exp(-b \cdot V_x)}{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}} \right\}^{\frac{n}{2}} \quad (15)$$

where  $I_{D2}$  represents  $I_o - I_{D2}$ . In this case, if the gain based on a second variable gain amplifier 201 and second gain control signal compensation circuit 202 (in the case shown in FIG. 2) or the second variable gain amplifier 201, fourth control signal compensation circuit 212, and first gain control signal compensation circuit 102 (in the case shown in FIG. 3) is expressed by

$$G_{CMP} = B \left\{ \frac{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}}{I_o} \right\}^{\frac{n}{2}} \quad (16)$$

where B is a constant of proportionality gain correction can be performed.

No specific problem arises if the circuit has characteristics that satisfy equation (16) regardless 5 of the number of second variable gain amplifiers 201 to be used.

The first and second embodiment will be described in detail next. FIG. 4 shows the detailed circuit arrangement of the first gain control signal 10 10 compensation circuit 102 in FIGS. 2 and 3. The following transistors are n-type MOSFETs (Nch MOSFETs) unless otherwise specified.

A transistor M1 has drain and gate terminals connected to each other.  $I_{D1}$  is input to the drain 15 terminal. The drain terminal of a transistor M2 is connected to a power supply voltage  $V_{DD}$ , and its source terminal is connected to the source terminal of the transistor M1 and grounded via a current source  $I_o$ . a given power supply  $V_{BB}$  is connected to the gate 20 terminal of the transistor M2. The current  $I_{D2}$  flowing in the drain terminal of the transistor M2 is the difference current between the current from the current source  $I_o$  and the current  $I_{D1}$  ( $I_{D2} = I_o - I_{D1}$ ). Referring to FIG. 4, the drain terminal of the 25 transistor M2 is connected to the power supply voltage  $V_{DD}$ . However, no problem arises even if the connection of the drain terminal changes as long as a current

flows to satisfy  $I_{D2} = I_o - I_{D1}$ .

Assume that in this circuit, as  $I_{D1}$  flows a current

$$I_{D1} = I_o \cdot \exp(-b \cdot v_x) \quad (17)$$

where b is a positive constant and  $V_X$  is the internal gain control signal output from a third gain control signal compensation circuit 300. The internal gain control signal  $V_X$  is converted into  $I_{D1}$  in equation (17) by a method that uses exponential characteristics based on bipolar transistors. Since this operation can be implemented by the technique used in Japanese Patent Application No. 10-370290 (Jpn. Pat. Appln. KOKAI Publication No. 2000-96386), a detailed description thereof will be omitted. As long as an exponential characteristic can be obtained by using a method different from that disclosed in Japanese Patent Application No. 10-370290, no problem arises if this method is used. Referring to FIG. 4, assuming that the circuit block for converting the internal gain control signal  $V_X$  into the current source  $I_{D1}$  is included in the current source  $I_{D1}$ , a description of the circuit of the exponential characteristic conversion section will be omitted. Also assuming that the transistors M1 and M2 have square characteristics, the transfer function of the first gain control signal compensation circuit 102 formed by the above circuit is expressed as

$$\begin{aligned} V_{z1} &= \sqrt{\frac{I_{D2}}{\beta}} - \sqrt{\frac{I_{D1}}{\beta}} \\ &= \frac{\sqrt{I_o \{1 - \exp(-b \cdot V_x)\}} - \sqrt{I_o \cdot \exp(-b \cdot V_x)}}{\sqrt{\beta}} \end{aligned} \quad (18)$$

Note that  $I_{D1}$  and  $I_{D2}$  are given by

$$I_{D1} = \beta (V_{GS1} - V_{TH})^2 \quad (19)$$

$$I_{D2} = \beta (V_{GS2} - V_{TH})^2 \quad (20)$$

5 The first variable gain amplifier 101 and second variable gain amplifier 201 shown in FIGS. 2 and 3 will be described next with reference to FIG. 5.

10 The first variable gain amplifier 101 will be described first. The drain terminal of a transistor M10 is connected to the power supply voltage  $V_{DD}$ , and its source terminal is connected to the source terminal of a transistor M11 and grounded through a current source  $I_{sig}$  including a desired signal to be gain-controlled. An output current  $I_{out}$  flows in the 15 drain terminal of the transistor M11.

The gain control signal  $V_{z1}$  which is an output signal from the first gain control signal compensation circuit 102 is applied between the gate terminals of the transistors M10 and M11.

20 Although a given voltage  $V_{BB}$  is applied to the gate electrode of the transistor M10, if this voltage has already been applied from the first gain control signal compensation circuit 102, the given voltage  $V_{BB}$  is not required. Although the above description is 25 associated with the first variable gain amplifier 101,

the same applies to the second variable gain amplifier 201. In the case of the second variable gain amplifier 201, however, the gain control signal  $V_{z2}$  as an output signal from the second gain control signal compensation circuit 202 or fourth control signal compensation circuit 212 is applied between the gate electrodes of the transistors M10 and M11.

The second gain control signal compensation circuit 202 in FIG. 2 and the fourth control signal compensation circuit 212 in FIG. 3 will be described next with reference to FIG. 6. The second gain control signal compensation circuit 202 is obtained by cascading a sixth gain control signal compensation circuit 122 which is similar to the first gain control signal compensation circuit 102, a voltage/current converter 400 represented by  $I_{z1} = f(V_{z1})$ , and a fifth gain control signal compensation circuit 112 which is similar to the first gain control signal compensation circuit 102. Note that an input current to the fifth gain control signal compensation circuit 112 is the sum current of the output current  $I_{z1}$  from the voltage/current converter and a predetermined DC bias current  $I_{BB}$ .

With a function that maximizes  $I_{z1}$  when  $I_{z1} = f(V_{z1})$  or  $V_{z1} = 0$  V (i.e.,  $I_{D1} = I_{D2}$ ), and gradually decreases  $I_{z1}$  as the absolute value of  $V_{z1}$  increases, gain correction can be realized by the second gain

control signal compensation circuit 202 and second variable gain amplifier 201. This operation will be described below.

When  $I_{D1} = I_{D2}$ , the first gain control signal compensation circuit 102 and first variable gain amplifier 101 in FIG. 2 decreases the gain by 3 dB. At this time,  $V_{z1}$  at the second gain control signal compensation circuit 202 becomes 0 V, and  $I_{z1}$  becomes a maximum current  $I_{z1,max}$ . Since the input signal to the fifth gain control signal compensation circuit 112 becomes a maximum value  $I_{z1,max} + I_{BB(A)}$ , a gain control signal  $V_{z2}$  which is an output voltage from the second gain control signal compensation circuit 202 is minimized. Therefore, the gain of the second variable gain amplifier 201 shown in FIG. 5 takes a maximum value. As the absolute value of  $V_{z1}$  increases,  $I_{z1}$  decreases. In this case, since the input current to the fifth gain control signal compensation circuit 112 decreases, the output voltage  $V_{z2}$  from the second gain control signal compensation circuit 202 increases. As a consequence, the gain of the second variable gain amplifier 201 in FIG. 5 decreases.

In summary, the second gain control signal compensation circuit 202 and second variable gain amplifier 201 operate such that the gain reaches a maximum value when  $V_{z1} = 0$  V, and decreases as the absolute value of  $V_{z1}$  increases. Therefore, the gain

deviation caused by the first gain control signal compensation circuit 102 and first variable gain amplifier 101 can be corrected by the second gain control signal compensation circuit 202 and second variable gain amplifier 201.

In this case, if the second embodiment (the variable gain circuit in FIG. 3) is used in place of the first embodiment (the variable gain circuit in FIG. 2), since the fourth control signal compensation circuit 212 in FIG. 3 receives the first gain control signal  $V_{z1}$  from the first gain control signal compensation circuit 102 in FIG. 3, the sixth gain control signal compensation circuit 122 in FIG. 6 or FIG. 7 is not required. Therefore, the circuit arrangement of the second embodiment shown in FIGS. 3 and 8 is smaller than that of the first embodiment shown in FIGS. 2 and 7. In the embodiment of FIG. 7, the currents  $i$  detected by current detectors CD, respectively, are amplified by current gain  $U$  to obtain the currents  $U \cdot i$ . The currents  $U \cdot i$  are added to the current sources  $I_{bias1}$  and  $I_{bias2}$ , respectively.

An example of a method of implementing the above voltage/current converter 400 with  $I_{z1} = f(V_{z1})$  will be described above with reference to FIG. 8, in a case where the following circuit having a square characteristic (square circuit)

$$I_{z1} = q \cdot I_o - m \cdot V_{z1}^2 \quad (21)$$

where  $q$  and  $m$  are constants is used.

FIG. 8 relates to the second embodiment. After the two first variable gain amplifiers 101 are cascaded, the resultant structure is connected to the gain deviation correction circuit made up of the fourth control signal compensation circuit 212 and second variable gain amplifier 201. Since the two first variable gain amplifiers 101 are cascaded, a gain  $G_{MOS2}$  becomes the square of equation (9) and expressed by

$$G_{MOS2} = \frac{I_o \cdot \exp(-b \cdot V_x)}{I_o + 2\sqrt{I_{D1} \cdot I_{D2}}} \quad (22)$$

Assume in this case that the current gain ( $U$ ) between the respective variable gain stages is 1.

According to equation (22), when  $I_{D1} = I_{D2}$ , the gain  $G_{MOS2}$  decreases by 6 dB. Gain correction can be attained by the voltage/current converter 400 and second variable gain amplifier 201 represented by equation (21). This will be described below. For the sake of simplicity, assume that the dimensional ratio between the respective transistors is 1, and  $I_{BB} = I_o/4$ . In this case, the dimensional ratio between the respective transistors corresponds to  $W/L$ , where  $W$  is the channel width and  $L$  is the channel length. In general, the channel length is constant.

In the above circuit arrangement, an input current  $I_A$  to the fifth gain control signal compensation circuit 112 is given by

$$\begin{aligned}
 I_A &= \frac{I_O}{4} + q \cdot I_O - m \cdot V_{z1}^2 \\
 &= \left( \frac{1}{4} + q \right) I_O - m \cdot V_{z1}^2 \\
 &= p \cdot I_O - m \cdot V_{z1}^2
 \end{aligned} \tag{23}$$

where  $p = 1/4 + q$ . The gain control signal  $V_{z1}$  input to the voltage/current converter 400 is given by

$$V_{z1} = \sqrt{\frac{I_{D2}}{\beta}} - \sqrt{\frac{I_{D1}}{\beta}} \tag{24}$$

Substitution of equation (24) into equation (23) yields  $I_A$  given by

$$I_A = \left( p - \frac{m}{\beta} \right) I_O + \frac{2m}{\beta} \sqrt{I_{D1} \cdot I_{D2}} \tag{25}$$

where  $I_{D2} = I_O - I_{D1}$ .

In this case, if the circuit is designed to set the output current  $I_{z1}$  from the voltage/current converter 400 to 0 A when  $I_{D1} = 0$  A,  $I_A$  and  $I_B$  are given by

$$I_A = \frac{1}{4} I_O + \frac{2m}{\beta} \sqrt{I_{D1} \cdot I_{D2}} \tag{26}$$

$$I_B = \frac{3}{4} I_O - \frac{2m}{\beta} \sqrt{I_{D1} \cdot I_{D2}} \tag{27}$$

In this case, the gain  $G_{CMP}$  of the second variable gain amplifier 201 is given by

$$\begin{aligned}
 G_{CMP1} &= \frac{\sqrt{I_A}}{\sqrt{I_A} + \sqrt{I_B}} \\
 &= \sqrt{\frac{I_A}{I_O + 2\sqrt{I_A \cdot I_B}}}
 \end{aligned} \tag{28}$$

If equations (26) and (27) are substituted into

equation (28), a gain  $G_{CMP1}$  of the second variable gain amplifier 201 is expressed as a function of  $I_{D1}$ .

5

To check any error between the gain  $G_{CMP}$  of an ideal variable gain amplifier and the gain  $G_{CMP1}$  of the second variable gain amplifier 201,  $G_{CMP}/G_{CMP,MAX}$  and  $G_{CMP1}/G_{CMP1,MAX}$ , which are obtained by normalizing the respective gains with maximum values, are compared with each other. Table 1 is a comparison table. Note that  $p = 0.9$ .

10

Table 1

$I_{D1}$	$G_{CMP}/G_{CMP,MAX}$	$G_{CMP}/G_{CMP1,MAX}$	difference
0	6 dB	-6.1 dB	-0.1 dB
0.05 $I_o$	-2.9 dB	-3.2 dB	-0.3 dB
0.1 $I_o$	-1.9 dB	-2.4 dB	-0.5 dB
0.2 $I_o$	-0.9 dB	-1.2 dB	-0.3 dB
0.3 $I_o$	-0.4 dB	-0.6 dB	-0.2 dB
0.4 $I_o$	-0.1 dB	-0.1 dB	0 dB
0.5 $I_o$	0 dB	0 dB	0 dB
0.6 $I_o$	-0.1 dB	-0.1 dB	0 dB
0.7 $I_o$	-0.4 dB	-0.6 dB	-0.2 dB
0.8 $I_o$	-0.9 dB	-1.2 dB	-0.3 dB
0.9 $I_o$	-1.9 dB	-2.4 dB	-0.5 dB
0.95 $I_o$	-2.9 dB	-3.2 dB	-0.3 dB
$I_o$	6 dB	-6.1 dB	-0.1 dB

15

According to Table 1, a gain deviation of 0.5 dB or less can be obtained by using the voltage/current converter 400 having square characteristics for  $I_{z1} = f(V_{z1})$ . This indicates that gain correction can be

satisfactorily achieved by the fourth control signal compensation circuit 212 and second variable gain amplifier 201.

An example of the voltage/current converter 400 used in the above case will be described next with reference to FIG. 9. The drain terminal of a transistor M30 is connected to the drain terminal of a transistor M33 and used as a negative current output terminal  $I^-$ . The drain terminal of a transistor M31 is connected to the drain terminal of a transistor M32 and used as a positive current output terminal  $I^+$ . The gate terminal of the transistor M30 is connected to the gate terminal of the transistor M31, to which one gain control signal  $V_{z1}$  is input. The gate terminal of the transistor M32 is connected to the gate terminal of the transistor M33, to which the other gain control signal  $V_{z1}$  is input. The source terminals of the transistors M30 and M32 are commonly connected and grounded through the current source  $I_o$ . A bias current from this current source  $I_o$  of the differential circuit, is also called a tail current. The source terminals of the transistors M31 and M33 are commonly connected and grounded through the current source  $I_o$ . The dimensional ratio between the transistors M30, M31, M32, and M33 is  $1 : K ; K : 1$ . Assume that the output current  $I_{z1}$  is obtained by the difference between  $I^+$  and  $I^-$ . The output current  $I_{z1}$  from the circuit having

this arrangement is given by

$$I_{z1} = 2 \frac{K-1}{K+1} I_o - 4 \frac{K(K-1)\beta}{(K+1)^2} - v_{z1}^2 \quad (29)$$

$$; |v_{z1}| \leq \sqrt{\frac{I_o}{K \cdot \beta}}$$

$$I_{z1} = - \frac{2K(K-1)\beta}{(K+1)^2} v_{z1}^2 + \frac{2K \cdot I_o}{K+1} - \frac{4K \cdot \beta \sqrt{\frac{(K+1)I_o}{\beta}} - K \cdot v_{z1}^2}{(K+1)^2} |v_{z1}| \quad (30)$$

$$; \sqrt{\frac{I_o}{K \cdot \beta}} \leq |v_{z1}| \leq \sqrt{\frac{I_o}{\beta}}$$

$$I_{z1} = 0 \quad (31)$$

$$; |v_{z1}| \leq \sqrt{\frac{I_o}{\beta}}$$

Obviously, as indicated by equation (29), square characteristics can be obtained within the range of  $|v_{z1}| \leq \sqrt{(I_o / (K \cdot \beta))}$ . Comparing equation (29) based on this circuit and equation (21), therefore, the second gain control signal compensation circuit 202 or fourth control signal compensation circuit 212 can be implemented by

$$q = 2 \frac{K-1}{K+1} \quad (32)$$

$$m = 4 \frac{K(K-1)\beta}{(K+1)^2} \quad (33)$$

Correction of a gain deviation unique to a MOSFET will be described next. FIG. 10 is a graph showing the input/output characteristics of the third gain control

signal compensation circuit 300 for correcting the gain deviation caused by the transition of the operation region of the MOSFET from a strong inversion region to a weak inversion region. The third gain control signal compensation circuit 300 has a gain a+b while an externally supplied external gain control signal  $V_c$  remains in the range of 0 V to  $V_{c1}$ , and has a gain a when the external gain control signal  $V_c$  becomes  $V_{c1}$  or higher. A corresponding internal gain control signal  $V_z$  is supplied to the first gain control signal compensation circuit 102 or second gain control signal compensation circuit 202. Although a constant b is determined by the exponential characteristic of the weak inverse region of the MOSFET, it generally takes a value almost equal to a. The internal gain control signal  $V_z$  can therefore expressed as

$$V_x = a \cdot V_c + b \cdot \min(V_c, V_{c1}) \quad (34)$$

where  $\min(V_c, V_{c1})$  takes a smaller value of  $V_c$  and  $V_{c1}$ . By using this third gain control signal compensation circuit 300, the gain deviation caused by the transition of the operation region of the MOSFET from a strong inversion to a weak inversion can be corrected. FIG. 11 shows a specific circuit for implementing such characteristics. In this circuit, the outputs of circuits 501 and 502 are commonly connected. One circuit 501 is formed by parallel-connecting two differential circuits and comprised of transistors M51

to M55, current sources  $I_o$ , and resistors  $R_1$ . The other circuit 502 is formed by parallel-connecting two differential circuits and comprised of transistors M56 to M62, current sources  $I_o$ , and resistors  $R_1$ . Note 5 that the transistors M52, M55, M58, and M61 are n-type FETs, and the remaining transistors are p-type FETs.

In the circuit 501, no current is output to the output terminal when the external gain control signal  $V_c$  is 0 V, and an output current  $I_x$  flows from the 10 output terminal as the external gain control signal  $V_c$  increases in level. The circuit 502 operates in the same manner as the circuit 501 except that the maximum 15 value of the source potential of M62 is limited by  $V_{BB11}$  and M62. For this reason, in the circuit 502, the output current is fixed when  $V_c$  becomes a given potential or higher.

In this circuit, the transconductance of the 20 circuits 501 and 502 is set to  $1/R_1$  when the external gain control signal  $V_c$  is at the given potential or lower. If different transconductances are to be set, the resistance  $R_1$  of the circuit 502 may be set to be 25 different from the resistance  $R_1$  of the circuit 501. In addition, in this circuit, the output is the current  $I_x$ . If, however, this current is flowed through a resistor, a voltage output can be obtained and converted into the external gain control signal  $V_c$  shown in FIG. 10.

As is obvious from the above description, the transconductances a and b shown in FIG. 10 can be obtained by setting the resistors R1 of the circuits 501 and 502 to a predetermined value.

5        According to the above description, desired signals (signals to be controlled) are a single-phase input and single-phase output. Even if these signals are a differential input and differential output, gain control can be realized in the same manner as described above. FIG. 12 shows a circuit in which the first variable gain amplifier 101 or second variable gain amplifier 201 is formed by a differential circuit.

10       FIG. 13 shows a circuit in which the variable gain circuit in FIG. 8 is formed by a differential circuit.

15       As described above, by using the present invention, the control voltage range for the external gain control signal  $V_c$ , in which the gain displayed in decibels linearly changes with respect to the externally supplied external gain control signal  $V_c$ , can be broadened. Therefore, gain control on a radio transceiver is facilitated. In addition, since the gain can be exponentially changed to a maximum gain, the S/N ratio can be maintained high.

20       The variable gain circuit may be constructed in a multi-stage configuration (two-stage configuration in the embodiment in FIG. 14).

25       FIG. 15 shows a radio transceiver circuit in a

portable telephone or another mobile radio communica-  
tion device, to which the variable gain circuit of the  
present invention is applied. Although the TDD (Time  
Division Duplex) scheme of time-divisionally switching  
5 transmission/reception will be exemplified here, the  
present invention is not limited to this.

According to the radio transceiver circuit, in  
transmission, two quadrature baseband signals  $I_{ch(TX)}$   
10 and  $Q_{ch(TX)}$  generated by a baseband signal generating  
section are output from a baseband processing section  
601 after being processed by a proper bandpass filter.  
In this case, a baseband is a signal to be transmitted.  
These baseband signals  $I_{ch(TX)}$  and  $Q_{ch(TX)}$  are input a  
quadrature modulator comprised of mixers 602 and 603  
15 and adder 604. This quadrature modulator modulates a  
second local oscillation signal having a frequency  $f_{L02}$ .  
The second local oscillation signal is generated by a  
local oscillator 801 and separated into two quadrature  
signals by a  $90^\circ$  phase shifter (90-PS) 802. These  
20 signals are then input to the quadrature modulator.

The modulated signal output from this quadrature  
modulator is an IF signal and input to a variable gain  
circuit 605. The variable gain circuit 605 is a  
variable gain circuit based on the present invention,  
25 and adjusts the input IF signal to a proper signal  
level in accordance with a gain control signal  
(corresponding to the external gain control signal  $V_c$ )

from a control system (not shown).

In this case, the IF signal is supplied as a current signal to the variable gain circuit 605. In the variable gain circuit described above, an output signal is extracted as a current signal. If a voltage signal is required as an output from the variable gain circuit 605, the current signal is converted into a voltage signal and output.

The IF signal output from the variable gain circuit 605 generally contains unwanted harmonics generated by the quadrature modulator and variable gain circuit 605. To remove the unwanted components, therefore, the IF signal is input to an up-converter 607 through a filter 606 formed by a low-pass filter (LPF) or bandpass filter (BPF).

The up-converter 607 multiplies the IF signal and a first local oscillation signal having a frequency  $f_{LO1}$  and generated by a first local oscillator 804 to generate an RF signal having a frequency  $f_{LO1}+f_{LO2}$  and an RF signal having a frequency  $f_{LO1}-f_{LO2}$ . One of these two RF signals is a desired wave, and the other is an unwanted image signal. In this case, the RF signal having the frequency  $f_{LO1}+f_{LO2}$  is used as a desired wave. However, the RF signal having the frequency  $f_{LO1}-f_{LO2}$  may be used as a desired wave. The image signal is removed by an image removing filter 608 formed by a BPF. The desired wave is amplified to a

predetermined power level by a power amplifier 609 and supplied to an antenna 806 through a transmission/reception switch (or duplexer) 805 to be radiated as a radio wave.

5       In reception, a reception RF signal output from the antenna 806 is input to a low-noise amplifier (LNA) 702 through the transmission/reception switch (or duplexer) 805 and a filter 701 formed by a BPF. The reception RF signal amplified by the LNA 702 is input  
10      to a down-converter 704 through an image removing filter 703 formed by a BPF.

15      The down-converter 704 multiplies a first local oscillation signal having a frequency  $f_{L01}$  and generated by the first local oscillator 804 and the reception RF signal to frequency-convert the reception RF signal into an IF signal. This IF signal passes through a filter 705 formed by a BPF and is input to a quadrature demodulator comprised of a divider (not shown) and mixers 707 and 708 through a gain control  
20      circuit 706.

25      This gain control circuit 706 is a variable gain circuit based on the present invention described above, like the variable gain circuit 605 on the transmission side. The gain control circuit 706 adjusts the input IF signal to a proper signal level in accordance with a gain control signal (corresponding to the external gain control signal  $V_c$ ) from a control system (not shown).

In this case as well, the IF signal is supplied as a current signal to the gain control circuit 706. If a voltage signal is required as an output from the gain control circuit 706, the current signal is converted 5 into a voltage signal and output it.

Quadrature second local oscillation signals having a frequency  $f_{LO2}$  are input from the local oscillator 801 to the above quadrature demodulator through a  $90^\circ$  phase shifter 803, as in the case of the quadrature 10 modulator on the transmission side. Outputs  $I_{ch}(RX)$  and  $Q_{ch}(RX)$  from this quadrature demodulator are input to a reception-side baseband processing section 709, in which the reception signal is demodulated to reproduce the original baseband signal.

15 In this application, the present invention is applied to the IF-stage variable gain circuits 605 and 706. However, when the power amplifier 609 on the transmission side or the LNA 702 on the reception side, which is a high-frequency circuit, is to be formed by a 20 variable gain circuit, the arrangement of the variable gain circuit of the present invention can be applied. Basically, in these cases, an IF signal is merely replaced with an RF signal as an input signal.

25 According to the present invention, there is provided a variable gain circuit using field-effect transistors, which can linearly adjust the gain displayed in decibels with respect to an externally

supplied gain control signal.

Additional advantages and modifications will readily occur to those skilled in the art. Therefore, the invention in its broader aspects is not limited to the specific details and representative embodiments shown and described herein. Accordingly, various modifications may be made without departing from the spirit or scope of the general inventive concept as defined by the appended claims and their equivalents.

WHAT IS CLAIMED IS:

1. A variable gain circuit comprising:
  - a variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor;
  - a gain control signal compensation circuit which outputs a gain control signal for controlling a gain of said variable gain amplifier and includes a second field-effect transistor; and
- 10 a gain deviation correction circuit which corrects a gain deviation based on said variable gain amplifier and said gain control signal compensation circuit.
- 15 2. The circuit according to claim 1, wherein said first variable gain amplifier comprises multi-stage amplifiers.
- 20 3. The circuit according to claim 1, which further comprises a gain control signal converter which converts an external gain control signal into an internal gain control signal, said variable gain amplifier including the first field-effect transistor is a first variable gain amplifier, the first gain control signal is a first gain control signal, said gain control signal compensation circuit including the second field-effect transistor is a first gain control signal compensation circuit, said gain deviation
- 25 correction circuit includes a second gain control signal compensation circuit and a second variable gain

amplifier, and said first gain control signal compensation circuit converts the internal gain control signal into the first gain control signal and inputs the first gain control signal to said first variable gain amplifier to control gain of said first variable gain amplifier, and said second gain control signal compensation circuit converts the internal gain control signal into the second gain control signal and inputs the second gain control signal to said second variable gain amplifier to control gain of said second variable gain amplifier.

4. The circuit according to claim 3, wherein said first variable gain amplifier comprises multi-stage amplifiers.

5. The circuit according to claim 3, wherein said second gain control signal compensation circuit comprises a circuit obtained by cascading a first gain control signal compensation circuit unit having a structure equivalent to that of said first gain control signal compensation circuit, a voltage/current converter unit, and a second gain control signal compensation circuit unit having an arrangement equivalent to that of said first gain control signal compensation circuit.

6. The circuit according to claim 5, wherein said first variable gain amplifier comprises multi-stage amplifiers.

7. The circuit according to claim 5, wherein said voltage/current converter unit converts the first gain control signal  $V_{z1}$  into a current signal  $I_{z1}$  according to  $I_{z1} = f(V_{z1})$ , where  $I_{z1}$  is an output current to be input to said second gain control signal compensation circuit unit,  $f$  is a function.

5 8. The circuit according to claim 7, wherein said first variable gain amplifier comprises multi-stage amplifiers.

10 9. The circuit according to claim 1, which further comprises a gain control signal converter which converts an external gain control signal into an internal gain control signal, said variable gain amplifier including the first field-effect transistor is a first variable gain amplifier, said gain control signal compensation circuit including the second field-effect transistor is a first gain control signal compensation circuit, said gain deviation correction circuit includes a second gain control signal compensation circuit and a second variable gain amplifier, said first gain control signal compensation circuit converts the internal gain control signal into a first gain control signal, said second gain control signal compensation circuit converts the first gain control signal into a second gain control signal, and the first gain control signal is input to said first variable gain amplifier to control a gain of said first

variable gain amplifier, and the second gain control signal is input to said second variable gain amplifier to control a gain of said second variable gain amplifier.

5 10. The circuit according to claim 9, wherein said first variable gain amplifier comprises multi-stage amplifiers.

10 11. The circuit according to claim 9, wherein said second gain control signal compensation circuit comprises a circuit obtained by cascading a voltage/current converter unit connected to an output of said first gain control signal compensation circuit, and a gain control signal compensation circuit unit having a structure equivalent to that of said first gain control 15 signal compensation circuit.

12. The circuit according to claim 11, wherein said first variable gain amplifier comprises multi-stage amplifiers.

20 13. The circuit according to claim 11, wherein said voltage/current converter unit converts the first gain control signal  $V_{z1}$  into a current signal  $I_{z1}$  according to  $I_{z1} = f(V_{z1})$ , where  $I_{z1}$  is an output current to be input to said second gain control signal compensation circuit unit,  $f$  is a function.

25 14. The circuit according to claim 13, wherein said first variable gain amplifier comprises multi-stage amplifiers.

15. A variable gain circuit comprising:

a first variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor;

5 a second variable gain amplifier which receives the amplified signal, outputs an amplified output signal, and includes a second field-effect transistor;

10 a first gain control signal compensation circuit which outputs a first gain control signal for controlling a gain of said first variable gain amplifier and includes a third field-effect transistor;

15 a second gain control signal compensation circuit which outputs a second gain control signal for controlling a gain of said second variable gain amplifier; and

20 a third gain control signal compensation circuit which receives an externally supplied external gain control signal, converts the external gain control signal into an internal gain control signal, and outputs the internal gain control signal to said first and second gain control signal compensation circuits.

16. A variable gain circuit comprising:

25 a first variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor;

a second variable gain amplifier which receives the amplified signal, outputs an amplified output

signal, and includes a second field-effect transistor;  
a first gain control signal compensation circuit  
which outputs a first gain control signal for  
controlling a gain of said first variable gain  
5 amplifier and includes a third field-effect transistor;  
a second gain control signal compensation circuit  
which receives the first gain control signal and  
outputs a second gain control signal for controlling a  
gain of said second variable gain amplifier; and  
10 a third gain control signal compensation circuit  
which receives an externally supplied external gain  
control signal, converts the external gain control  
signal into an internal gain control signal, and  
outputs the internal gain control signal to said first  
15 gain control signal compensation circuit.

17. The circuit according to claim 16, wherein  
said second gain control signal compensation circuit  
and said second variable gain amplifier compensate a  
gain deviation caused when the first field-effect  
20 transistor of said first variable gain amplifier and  
the third field-effect transistor of said first gain  
control signal compensation circuit operate in a strong  
inversion region.

18. The circuit according to claim 16, wherein  
25 said third gain control signal compensation circuit  
compensates a gain deviation caused when the first  
field-effect transistor of said first variable gain

amplifier and the third field-effect transistor of said first gain control signal compensation circuit operate in a weak inversion region.

19. The circuit according to claim 16, wherein  
5 said first variable gain amplifier includes a first pair of field-effect transistors, the first gain control signal being input between gate terminals of the first pair of field-effect transistors, source terminals of the first pair of field-effect transistors  
10 being commonly connected and grounded through a first current source including the input signal, and said second variable gain amplifier includes a second pair of field-effect transistors, the second gain control signal being input between gate terminals of the second  
15 pair of field-effect transistors, source terminals of the second pair of field-effect transistors being commonly connected and grounded through a second current source including the amplified signal.

20. The circuit according to claim 16, wherein  
20 said first gain control signal compensation circuit includes a first pair of field-effect transistors, the internal gain control signal being input between gate terminals of the first pair of field-effect transistors, source terminals of the first pair of field-effect  
25 transistors being commonly connected and grounded through a first current source including a given current, and said second gain control signal

compensation circuit includes a voltage/current converter represented by  $I_{z1} = f(V_{z1})$  where  $f$  indicates a function and  $V_{z1}$  indicates the amplified signal of said first variable gain amplifier and a second pair of field-effect transistors, the second gain control signal being input between gate terminals of the second pair of field-effect transistors, source terminals of the second pair of field-effect transistors being commonly connected and grounded through a second current source including the amplified signal, and a drain terminal of one of the second pair of field-effect transistors being connected to said voltage/current converter.

ABSTRACT OF THE DISCLOSURE

A variable gain circuit includes a variable gain amplifier which receives an input signal, outputs an amplified signal, and includes a first field-effect transistor, a gain control signal compensation circuit which outputs a gain control signal for controlling the gain of the variable gain amplifier and includes a second field-effect transistor, and a gain deviation correction circuit which corrects a gain deviation based on the variable gain amplifier and the gain control signal compensation circuit.

FIG. 1A

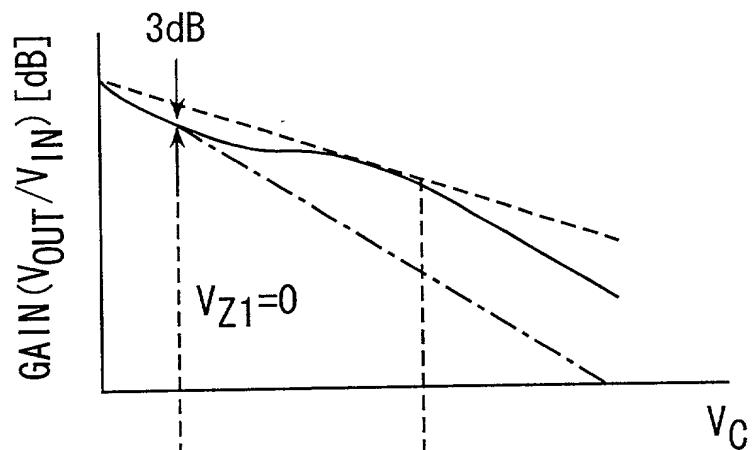


FIG. 1B

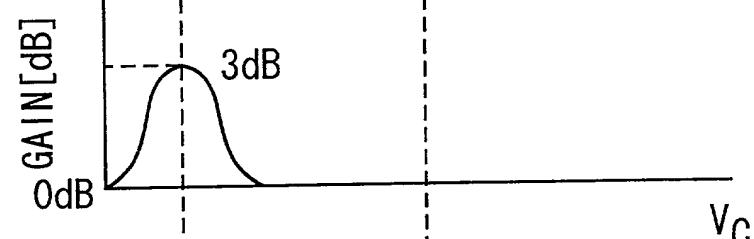


FIG. 1C

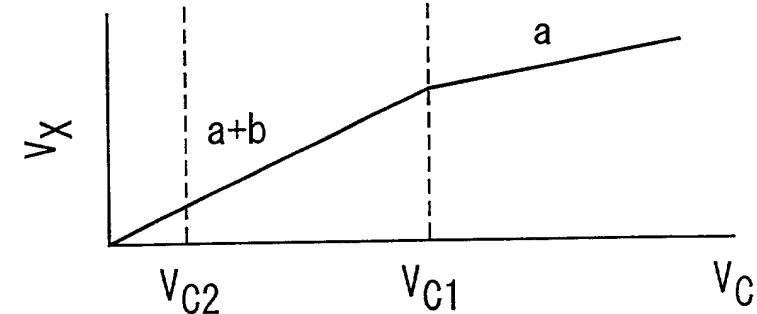
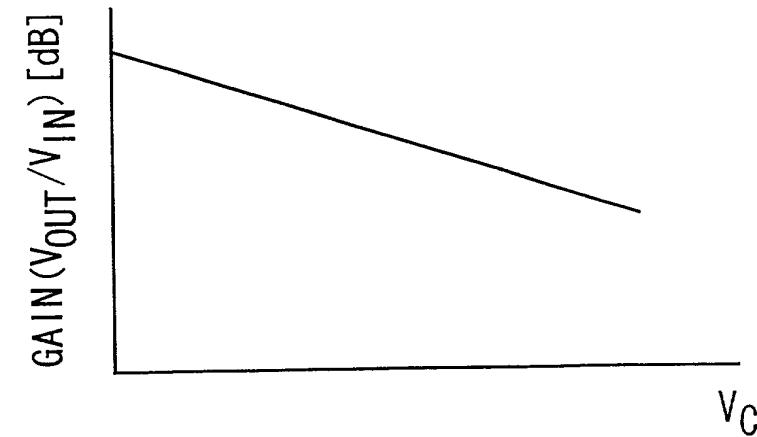


FIG. 1D



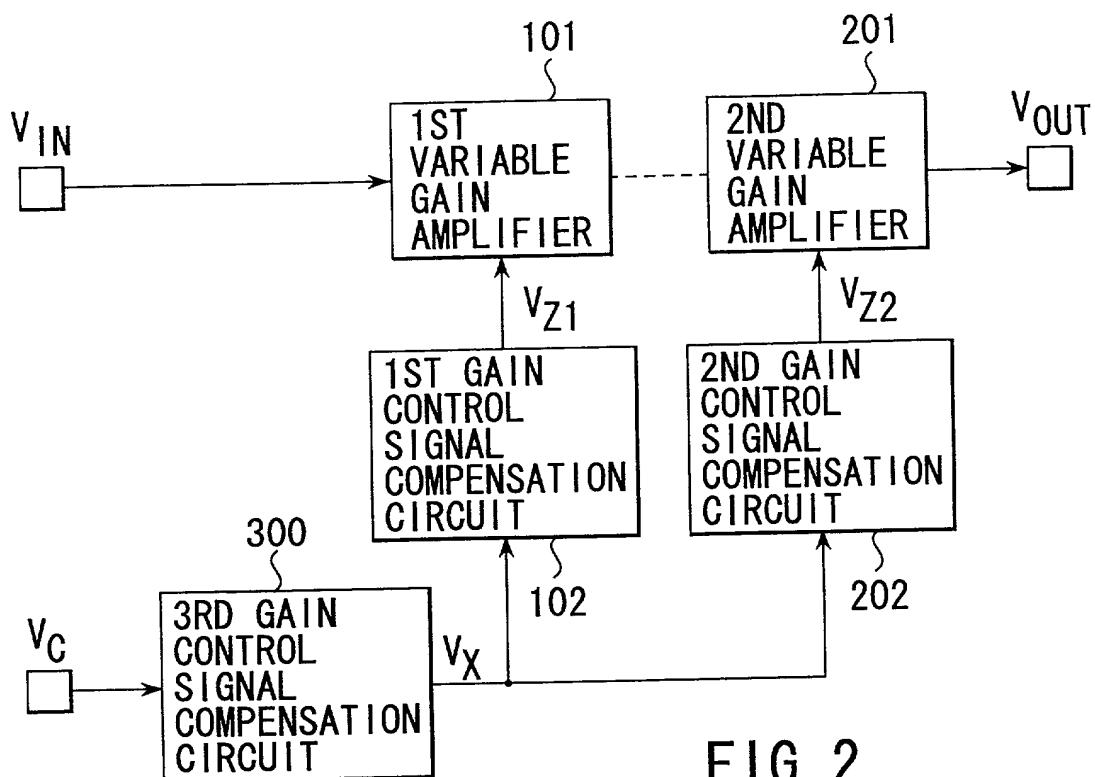


FIG. 2

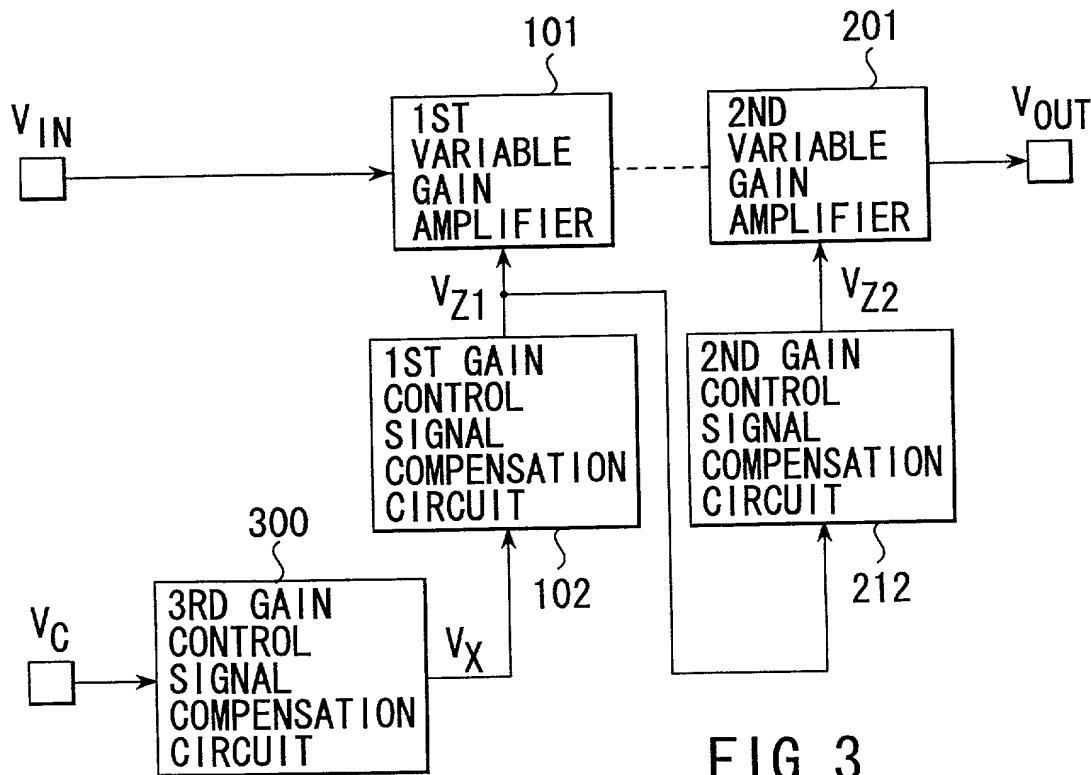


FIG. 3

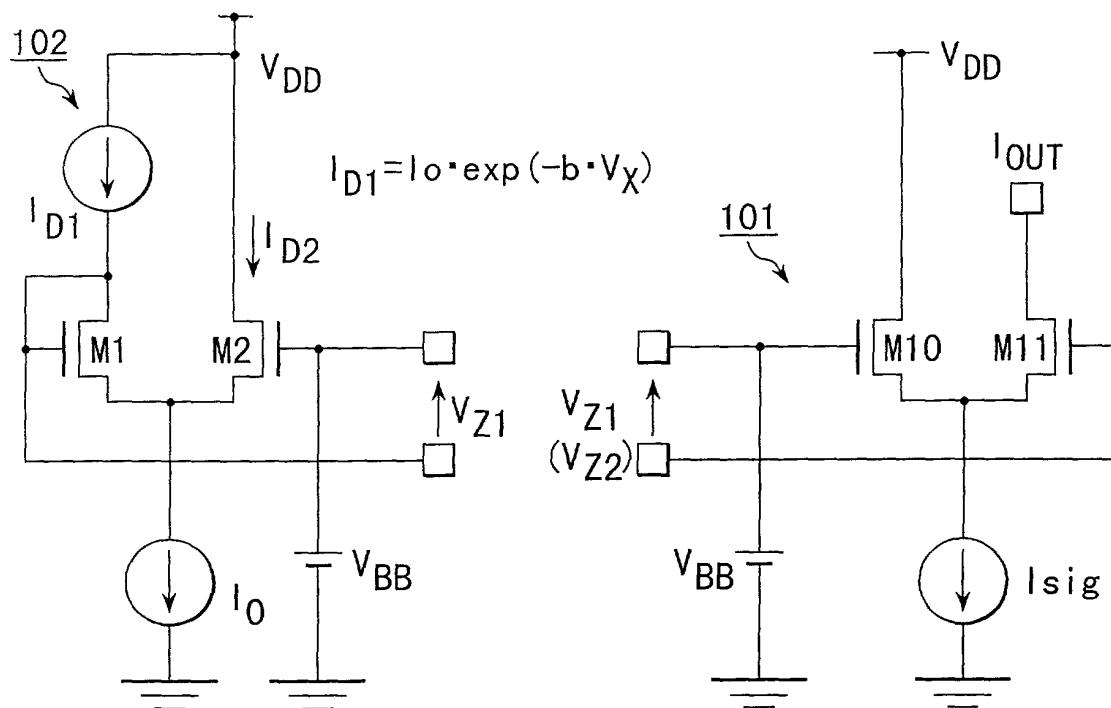
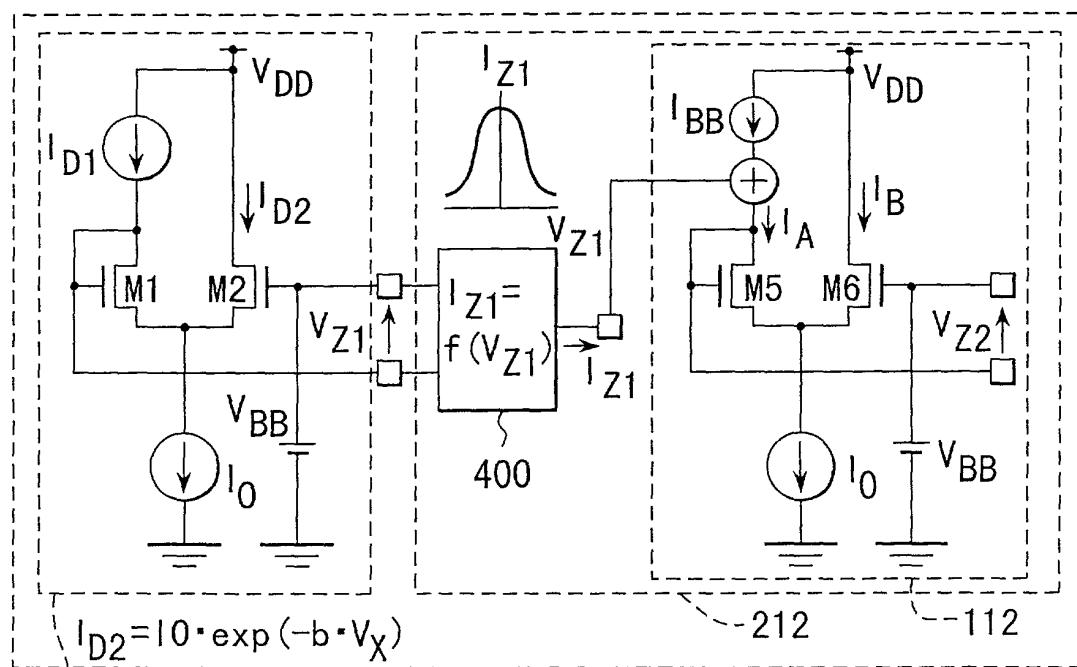


FIG. 4

FIG. 5



122

FIG. 6

202

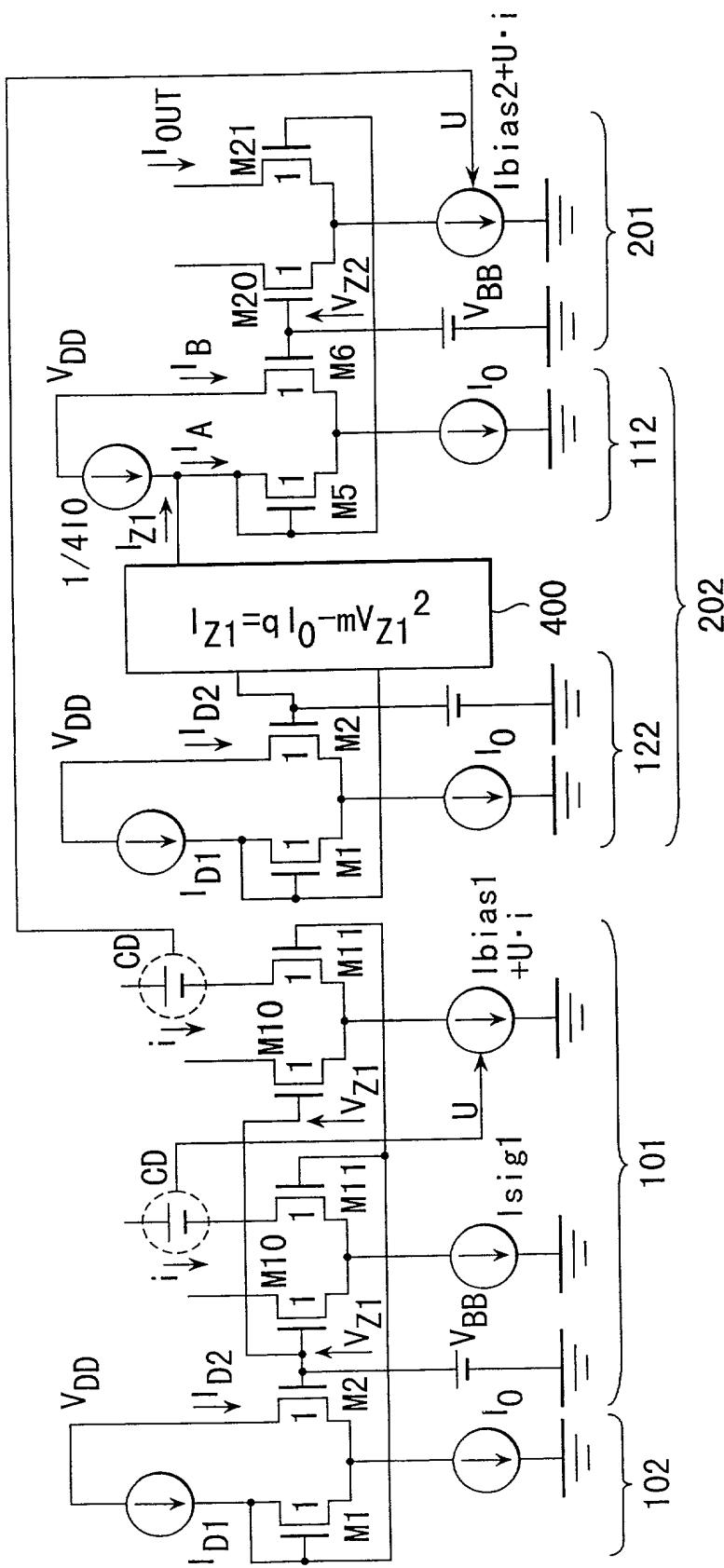


FIG. 7

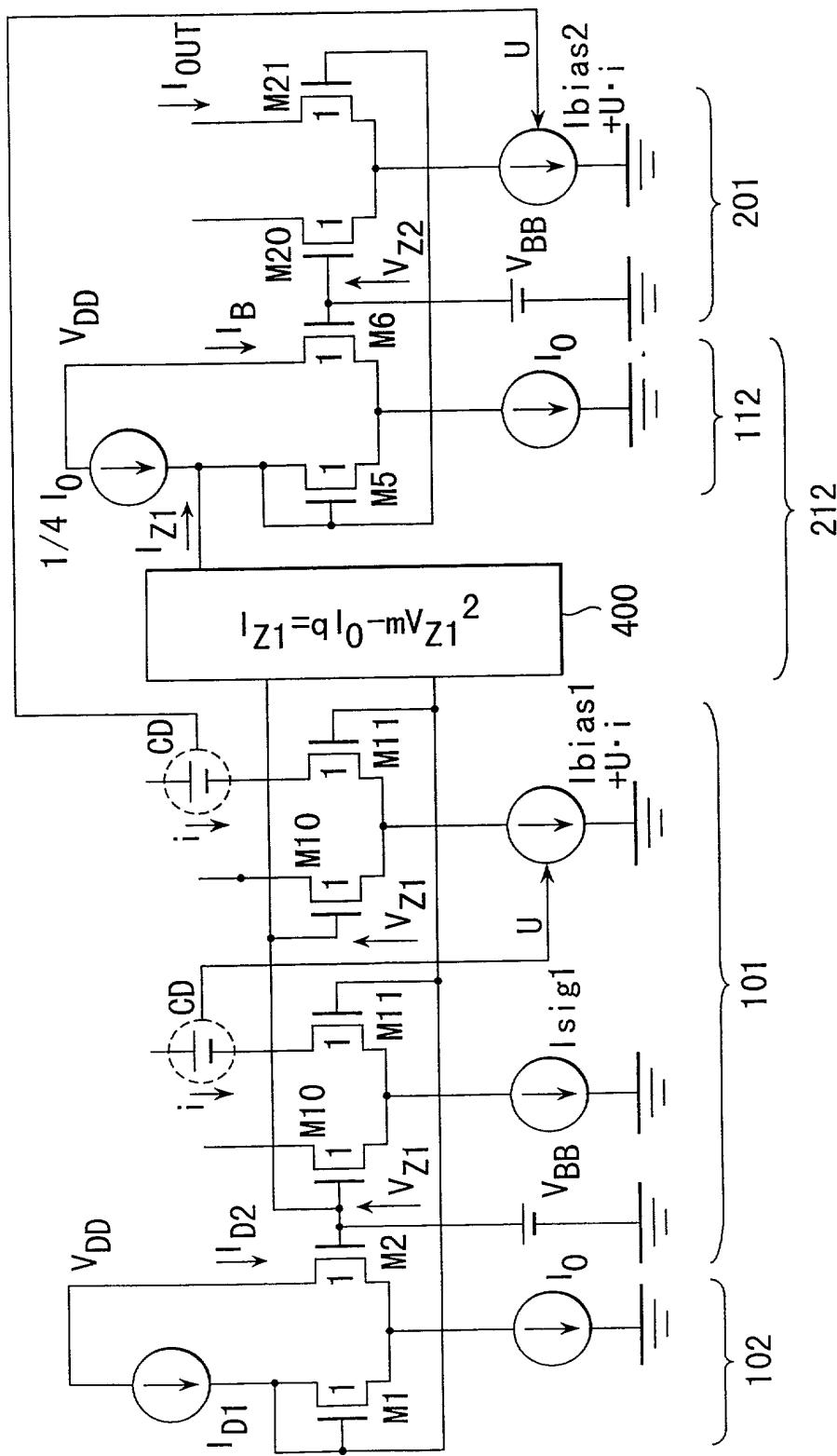


FIG. 8

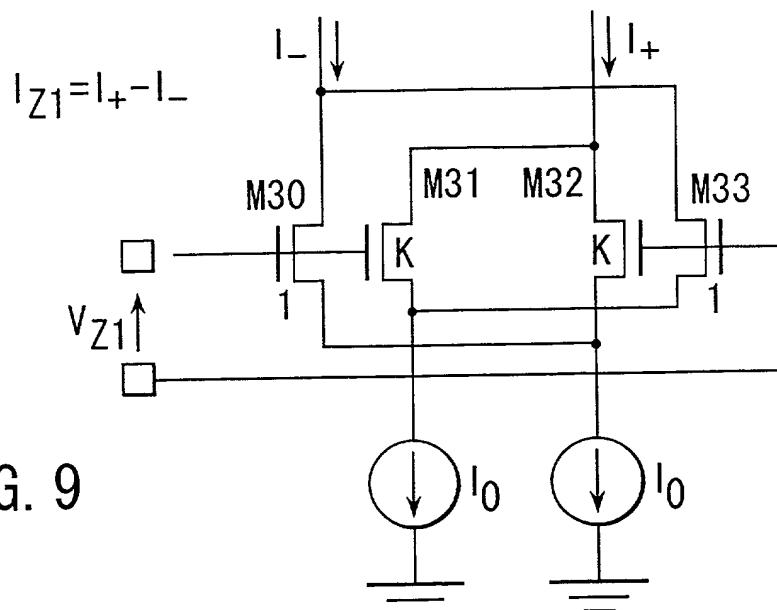


FIG. 9

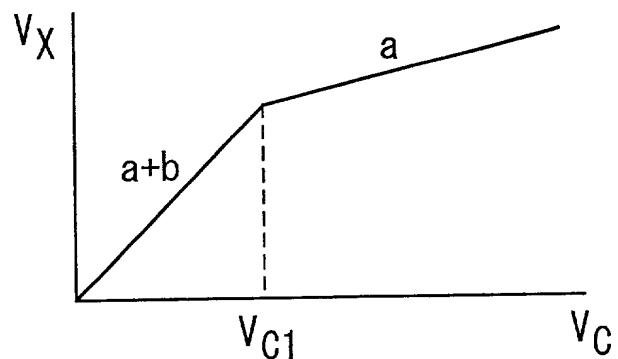


FIG. 10

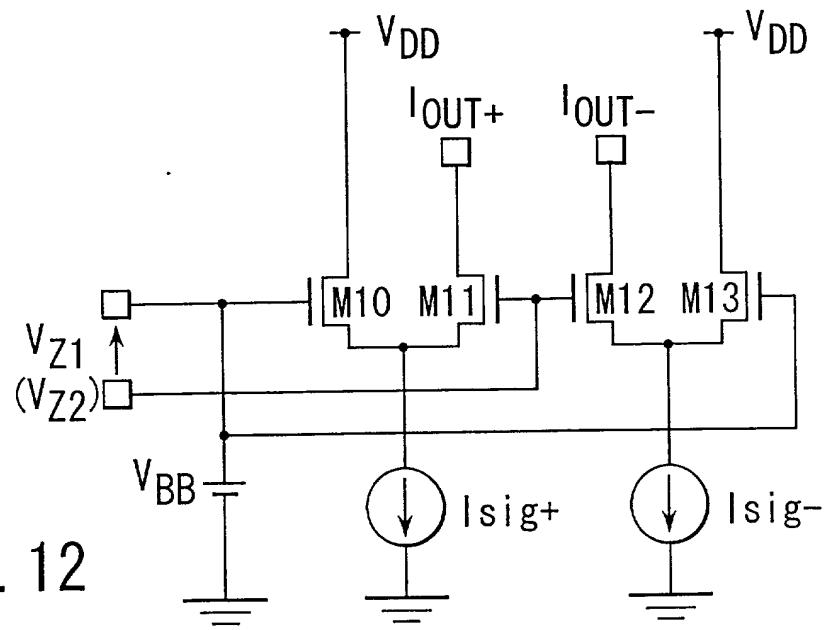
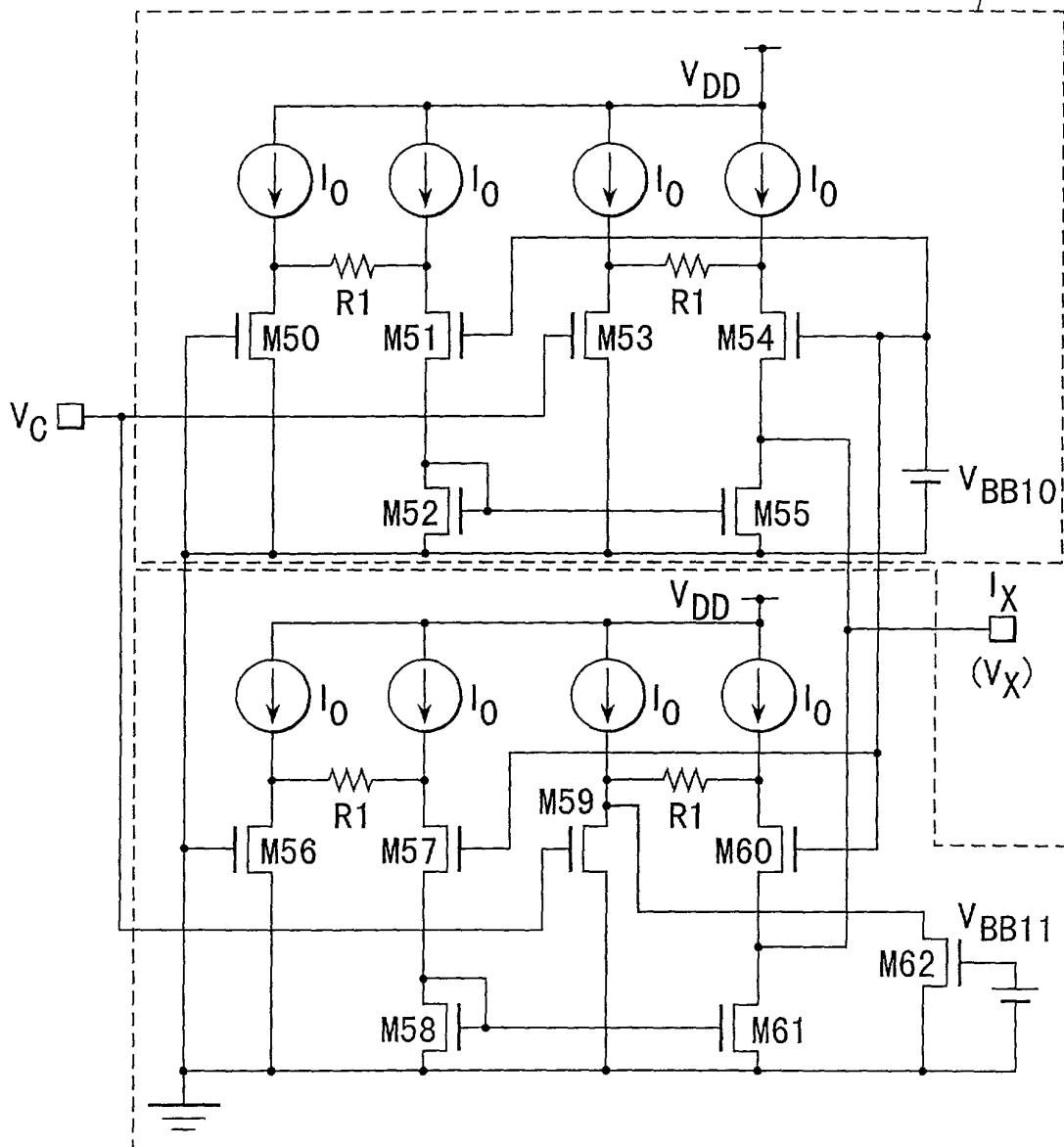


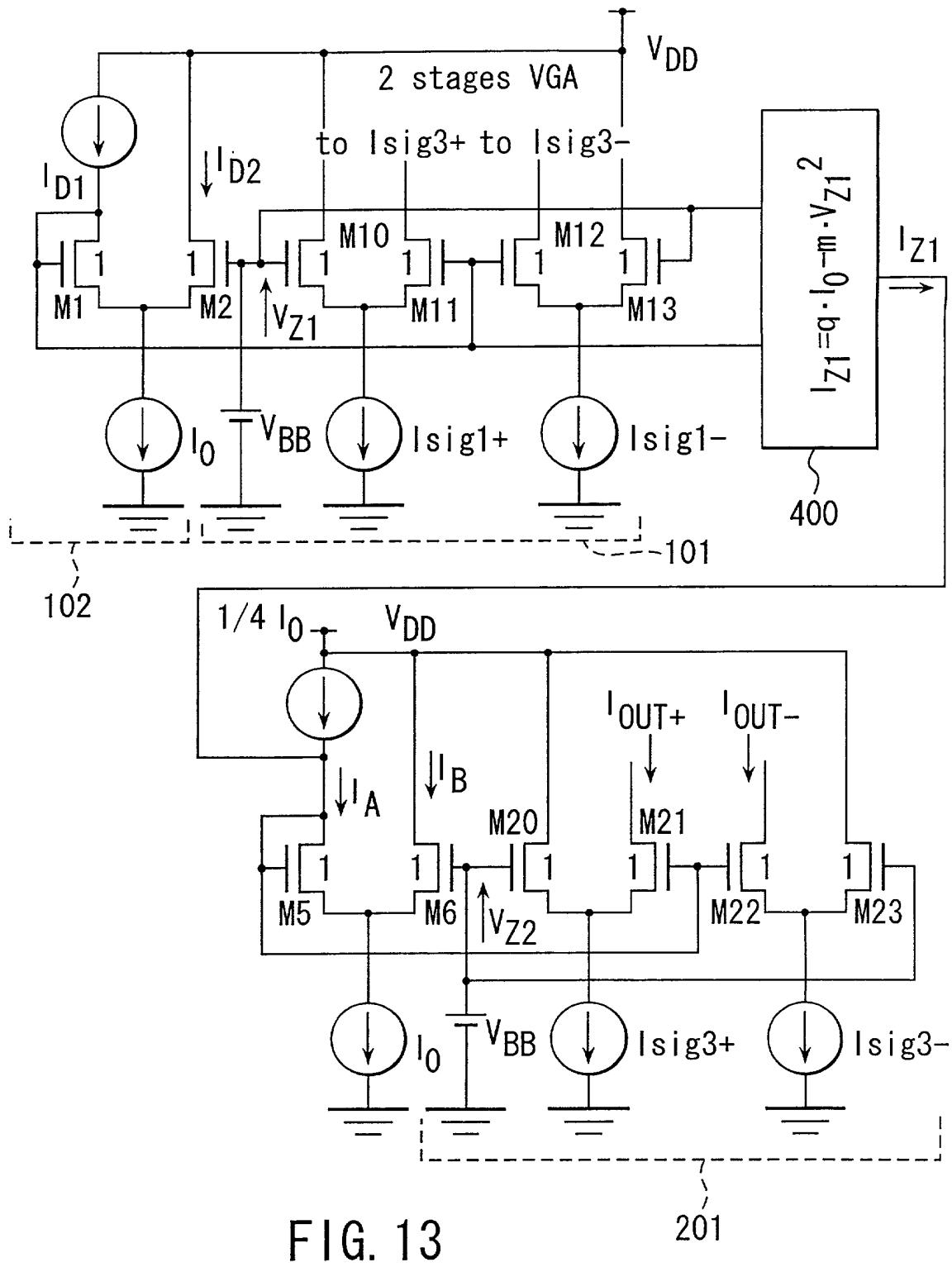
FIG. 12

501



502

FIG. 11



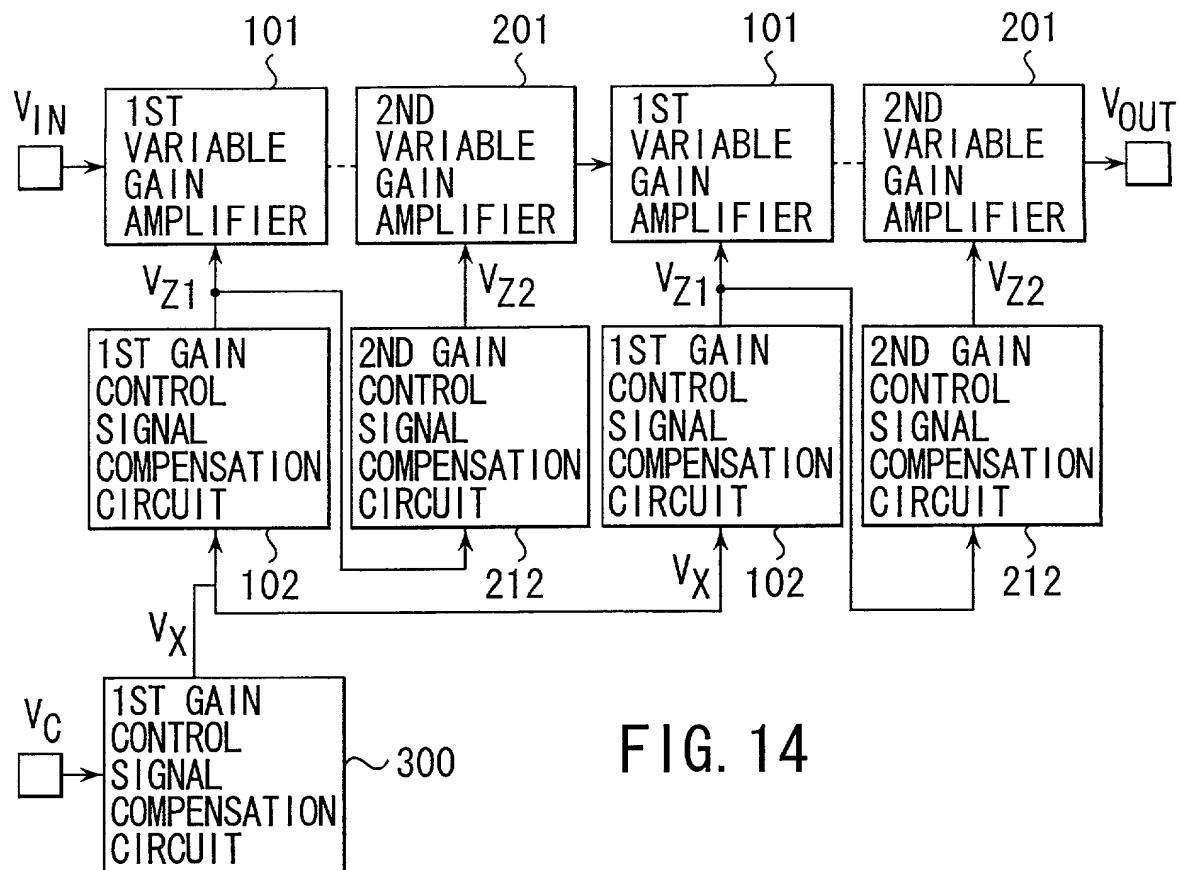


FIG. 14

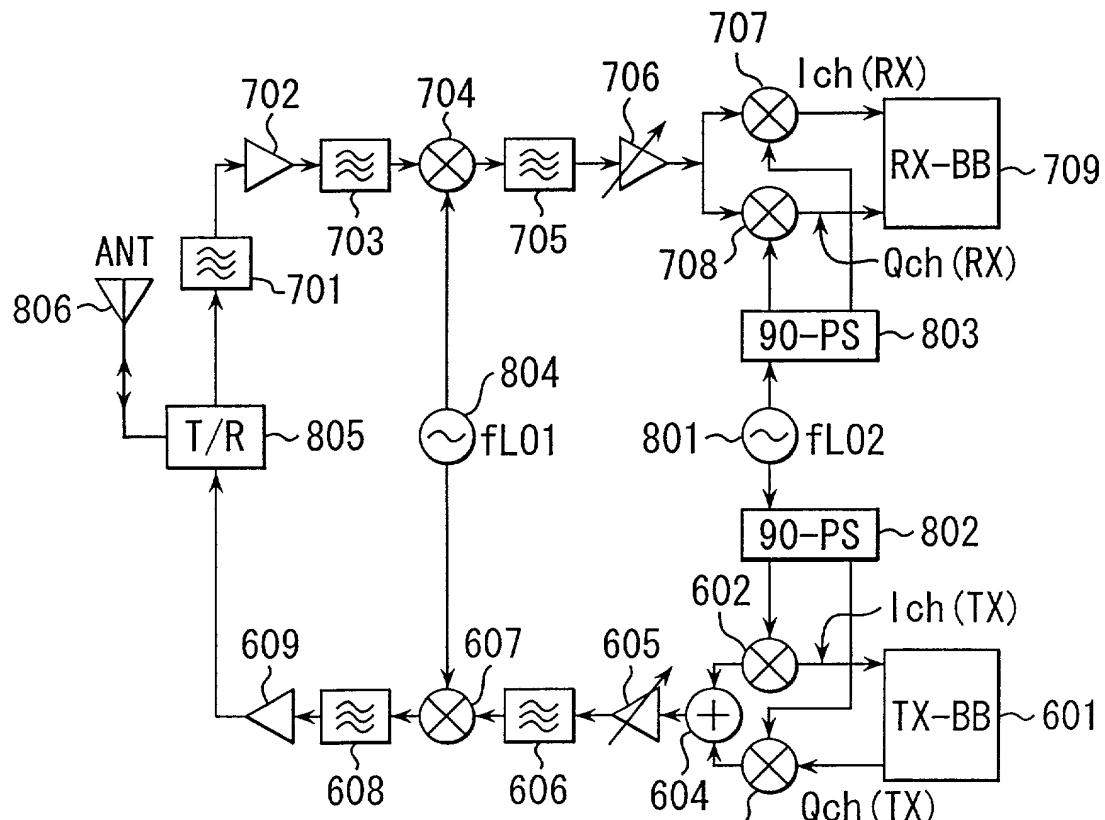


FIG. 15

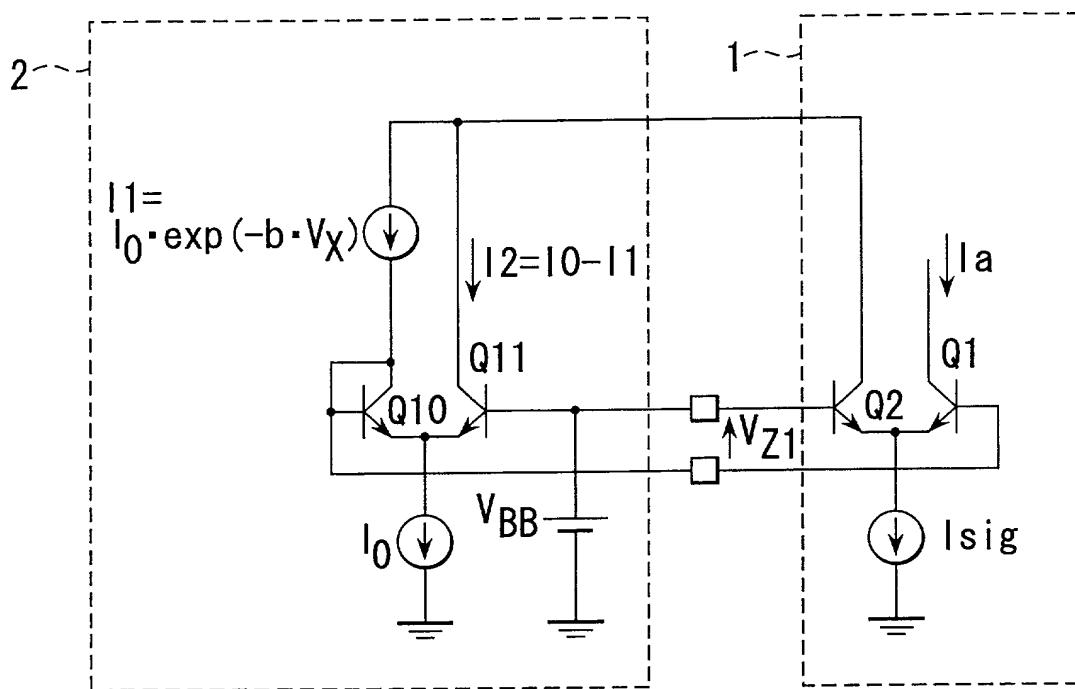


FIG. 16

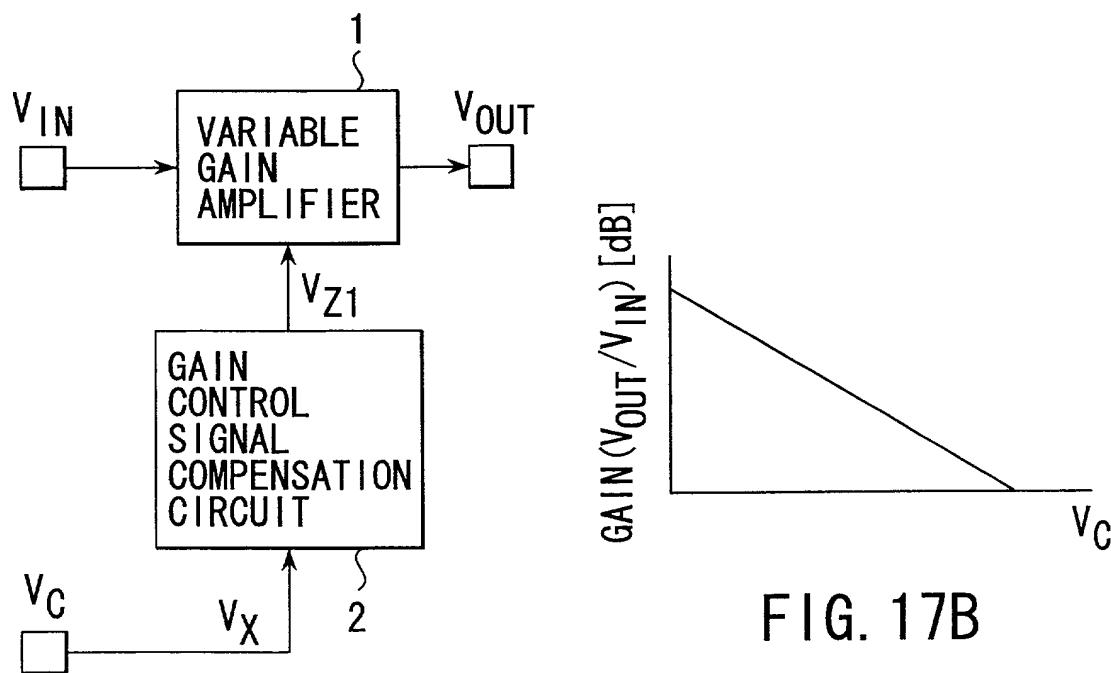


FIG. 17A

FIG. 17B

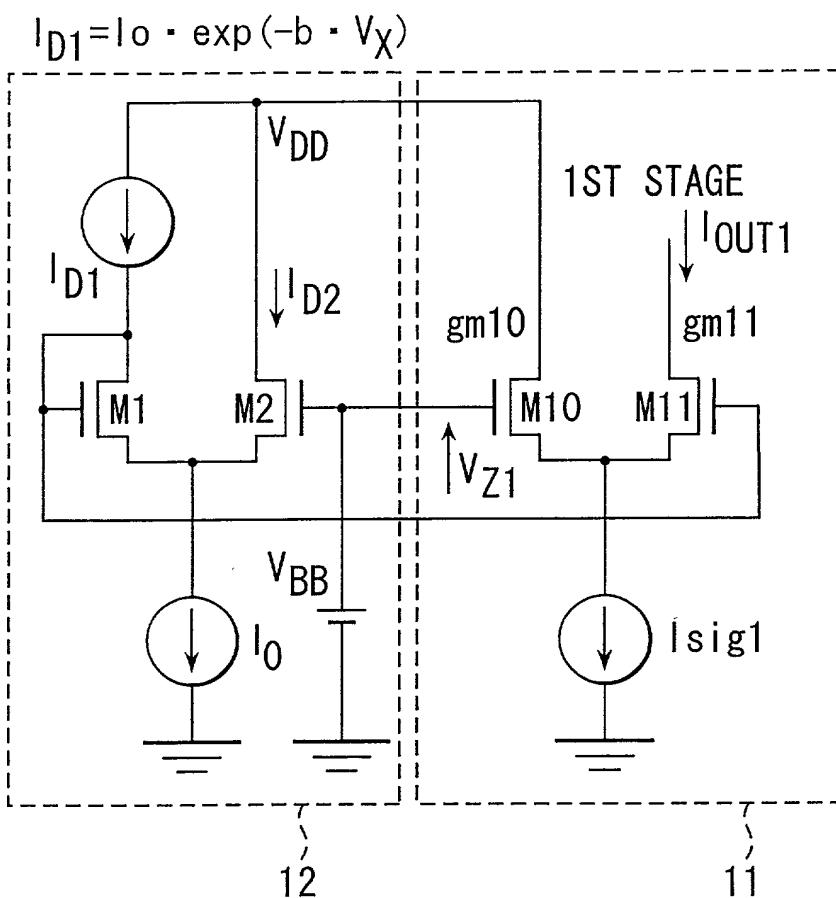


FIG. 18

## DECLARATION FOR PATENT APPLICATION

As a below named inventor, I declare:  
 that I verily believe myself to be the original, first and sole (if only one individual inventor is listed below) or an original, first and joint inventor (if more than one individual inventor is listed below) of the invention in

## VARIABLE GAIN CIRCUIT

the specification of which is attached hereto unless the following box is checked.

was filed on \_\_\_\_\_ as United States Application  
 or PCT International Application No. \_\_\_\_\_, and  
 was amended on \_\_\_\_\_ (if applicable).

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information of which is material to patentability as defined in 37 CFR 1.56.

I hereby claim foreign priority benefits under 35 U.S.C. 119(a)-(d) or 365(b) of any foreign application(s) for patent or inventor's certificate, or 35 U.S.C. 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed:

<u>Country</u>	<u>Category</u>	<u>Application No.</u>	<u>Filing Date</u>	<u>Priority Claim</u>
Japan	Patent	11-306798	October 28, 1999	Yes
Japan	Patent	2000-284708	September 20, 2000	Yes

And I hereby appoint Norman F. Oblon (Reg. No. 24, 618), Marvin J. Spivak (Reg. No. 24, 913), C. Irvin McClelland (Reg. No. 21, 124), Gregory J. Maier (Reg. No. 25, 599), Arthur I. Neustadt (Reg. No. 24, 854), Richard D. Kelly (Reg. No. 27, 757), James D. Hamilton (Reg. No. 28, 421), Eckhard H. Kuesters (Reg. No. 28, 870), Robert T. Pous (Reg. No. 29, 099), Charles L. Gholz (Reg. No. 26, 395), Vincent J. Sunderdick (Reg. No. 29, 004), William E. Beaumont (Reg. No. 30, 996), Robert F. Gnuse (Reg. No. 27, 295), Jean-paul Lavallee (Reg. No. 31, 451), Stephen G. Baxter (Reg. No. 32, 884), Robert W. Hahl (Reg. No. 33, 893), Richard L. Treanor (Reg. No. 36, 379), Steven P. Weihrouch (Reg. No. 32, 829), John T. Goolkasian (Reg. No. 26, 142), Richard L. Chinn (Reg. No. 34, 305), Steven E. Lipman (Reg. No. 30, 011), Carl E. Schlier (Reg. No. 34, 426), James J. Kulbaski (Reg. No. 34, 648), Richard A. Neifeld (Reg. No. 35, 299), J. Derek Msao (Reg. No. 35, 270), Surinder Sachar (Reg. No. 34, 423), Christina M. Gadiano (Reg. No. 37, 628), Jeffrey B. McIntyre (Reg. No. 36, 867), Paul E. Rauch (Reg. No. 38, 591), William T. Enos (Reg. No. 33, 128) and Michael E. McCabe, Jr., (Reg. No. 37, 182) each of whose address is Fourth Floor, 1755 Jefferson Davis Highway, Arlington, Virginia 22202, or any one of them, my attorneys with full power of substitution and revocation, to prosecute this application and to transact all business in the Patent & Trademark Office connected therewith, and request that correspondence be directed to Oblon, Spivak, McClelland, Mailer & Neustadt, P.C., Fourth Floor, 1755 Jefferson Davis Highway, Arlington, Virginia 22202.

I declare further that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

## DECLARATION FOR PATENT APPLICATION

I declare further that my post office address is at c/o Intellectual Property Division, KABUSHIKI KAISHA TOSHIBA, 1-1 Shibaura 1-chome, Minato-ku, Tokyo 105-8001, Japan; and that my citizenship and residence are as stated below next to my name:

Inventor: (Signature)

Date

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Shoji Otaka

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*Osamu Watanabe*  
Osamu Watanabe

Date: OCT. 18. 2000

Citizen of: Japan Yokohama-shi, Japan

Date: \_\_\_\_\_

Citizen of: Japan \_\_\_\_\_

Date: \_\_\_\_\_

Citizen of: Japan \_\_\_\_\_